RENESAS

ISL68225, ISL68236

Digital Dual Output, 9-Phase PWM Controller

The <u>ISL68225</u> and <u>ISL68236</u> are digital dual output multiphase (X+Y \leq 9) PWM controllers supporting PMBus V1.3/AVSBus interfaces. The controllers can be configured to support phase assignments up to a maximum of nine phases across the two outputs (X and Y). For example, 8+1, 7+2, 6+3, 5+4, or a single output operation as a 9+0 configuration is supported. Increased power density and PMBus V1.3 interface support allow the devices to support any demanding power supply requirement.

Additionally, the ISL68236 with AVSBus complements PMBus by providing a common high-speed interface to accelerate point-to-point communication between the controller and load to statically and dynamically control the processor voltage and deliver a balanced, power efficient design.

The ISL68225 and ISL68236 use the proprietary Renesas digital synthetic current modulation scheme to achieve the industry-best combination of transient response, ease of tuning, and efficiency across the full load range. Diode emulation and automatic phase add/drop features allow you to extract maximum efficiency from the converter regardless of load conditions. You can use the intuitive Renesas PowerNavigator™ software to configure and monitor the device.

With minimal external components, easy configuration, robust fault management, and highly accurate regulation capability, implementing a high-performance, multiphase regulator has never been easier.

Applications

- DDR memory solutions
- Artificial intelligence/accelerator cards (FPGA, ASIC)
- · Network equipment
- Server/storage equipment
- Telecom/datacom equipment
- Point-of-load power supply (DSP, ASIC, FPGA)

Features

- · Advanced linear digital modulation scheme
 - Auto phase add/drop with PFM mode for excellent load vs efficiency profile
 - Dual edge modulation with optional diode braking for faster transient response
 - Excellent V_{OUT} transition performance
 - Zero latency synthetic current control for excellent high frequency current balance
- Flexible phase assignment from 0 to 9 phases per output
- Up to 2MHz switching frequency operation for high density designs
- Differential remote voltage sensing supports ±0.5% closed-loop system accuracy over load, line, and temperature
- Highly accurate current sensing for excellent load-line regulation and accurate OCP
 - Supports the full range of Renesas Smart Power Stage (SPS) devices
- Comprehensive fault management enables high reliability systems
 - Pulse-by-pulse (per phase) and total output current limiting
 - Black Box status recording capability with first fault indicator
- Intuitive configuration using <u>PowerNavigator</u>
- SMBus/PMBus V1.3 compatible
- Up to 16 user configurations stored in device Non-Volatile Memory (NVM)

Related Literature

For a full list of related documents, visit our website:

<u>ISL68225</u> and <u>ISL68236</u> device pages



Contents

1.	Overview	. 6
1.1	Typical Applications	. 6
1.2	Internal Block Diagrams.	. 9
1.3	Ordering Information	11
1.4	Pin Configurations	12
1.5	Functional Pin Descriptions	13
2.	Specifications	4.4
	•	
2.1	Absolute Maximum Ratings	
2.2	Thermal Information.	
2.3	Recommended Operating Conditions	
2.4	Electrical Specifications	15
3.	Initializing the Device	18
3.1	Power-On Reset (POR)	18
3.2	Selecting the PMBus Address	19
3.3	Selecting the User Configurations	
3.4	Configuring the Device	
4.	Operating the Device	
4.1	Input Voltage Sensing	
4.2	Lossless Input Current and Power Sensing	
4.3	VMON Voltage Sensing	
4.4	Enabling and Soft-Starting the Device	
4.5	Disabling the Device	
4.6	Phase Configuration and Automatic Phase Dropping	
4.7	Diode Emulation and PFM Operation	
4.8	Diode Braking	
4.9	Switching Frequency	24
4.10	0 Output Current Sensing	24
5.	Temperature Sensing	27
5.1	SPS Temperature Sensing	
5.2	NTC Temperature Sensing	
5.3	Temperature Compensation	
6.	Fault Monitoring and Protection.	
6.1	Power-Good Signals	
6.2	Overvoltage/Undervoltage Protection	
6.3	Output Overcurrent Protection	
6.4	Smart Power Stage OC Fault Detect.	
6.5	Thermal Protection and nVRHOT	
6.6	Catastrophic Failure Protection	
6.7	Black Box Recorder	32
7.	Layout and Design Considerations	33
7.1	Pin Noise Sensitivity, Design, and Layout Consideration	33



8.	PMBus Protocol	34
8.1	Send Byte Protocol	34
8.2	Write Byte/Word Protocol.	34
8.3	Read Byte/Word Protocol	35
8.4	Group Command Protocol	35
8.5	Alert Response Address	35
9.	PMBus Command Summary	36
9.1	PMBus Use Guidelines	
9.2	PMBus Data Formats	
	PMBus Command Detail	
10.1		
10.2		
10.3		
10.4		
10.5		
10.6		
10.7		
10.8	_ ()	
10.9		
10.1	0 SMBALERT_MASK (1Bh)	46
10.1		
10.1	2 VOUT_COMMAND (21h)	47
10.1	3 VOUT_TRIM (22h)	47
10.1		
10.1	5 VOUT_MAX (24h)	48
10.1	6 VOUT_MARGIN_HIGH (25h)	49
10.1	7 VOUT_MARGIN_LOW (26h)	49
10.1	8 VOUT_TRANSITION_RATE (27h)	50
10.1	9 VOUT_DROOP (28h)	50
10.2	_ ()	
10.2	1 FREQUENCY_SWITCH (33h)	51
10.2	2 POWER_MODE (34h)	52
10.2	3 VIN_ON (35h)	53
10.2	4 VIN_OFF (36h)	53
10.2	5 VOUT_OV_FAULT_LIMIT (40h)	54
10.2	6 VOUT_OV_FAULT_RESPONSE (41h)	55
10.2	7 VOUT_UV_FAULT_LIMIT (44h)	56
10.2	8 VOUT_UV_FAULT_RESPONSE (45h)	57
10.2	9 IOUT_OC_FAULT_LIMIT (46h)	58
10.3	0 IOUT_OC_FAULT_RESPONSE (47h)	59
10.3	1 OT_FAULT_LIMIT (4Fh)	60
10.3	2 OT_FAULT_RESPONSE (50h)	61
10.3	3 OT_WARN_LIMIT (51h)	62
10.3	4 UT_FAULT_LIMIT (53h)	62
10.3	5 UT_FAULT_RESPONSE (54h)	63
10.3	6 VIN_OV_FAULT_LIMIT (55h)	64
10.3	7 VIN_OV_FAULT_RESPONSE (56h)	65
10.3	8 VIN_OV_WARN_LIMIT (57h)	66



10.39	VIN_UV_WARN_LIMIT (58h)	66
10.40	VIN_UV_FAULT_LIMIT (59h)	67
10.41	VIN_UV_FAULT_RESPONSE (5Ah)	68
10.42	IIN_OC_FAULT_LIMIT (5Bh)	69
10.43	IIN_OC_FAULT_RESPONSE (5Ch)	70
10.44	IIN_OC_WARN_LIMIT (5Dh)	
10.45	TON_DELAY (60h)	
10.46	TON_RISE (61h)	
10.47	TOFF_DELAY (64h)	
10.48	TOFF FALL (65h)	
10.49	STATUS_BYTE (78h)	
10.50	STATUS_WORD (79h)	
10.51	STATUS_VOUT (7Ah)	
10.52	STATUS_IOUT (7Bh).	
10.53	STATUS_INPUT (7Ch)	
10.54	STATUS_TEMPERATURE (7Dh)	
10.55	STATUS_CML (7Eh)	
10.56	STATUS_MFR_SPECIFIC (80h)	
10.57	READ_VIN (88h)	
10.57	READ_IIN (89h)	
10.50	READ_VOUT (8Bh)	
10.59	READ_IOUT (8Ch)	
10.60	READ_TEMPERATURE_1 (8Dh)	
10.61		
	READ_TEMPERATURE_2 (8Eh)	
10.63	READ_TEMPERATURE_3 (8Fh)	
10.64	READ_POUT (96h)	
10.65	READ_PIN (97h)	
10.66	PMBUS_REVISION (98h)	
10.67	MFR_ID (99h)	
10.68	MFR_MODEL (9Ah).	
10.69	MFR_REVISION (9Bh)	
10.70	MFR_DATE (9Dh)	
10.71		
10.72		
10.73	DMAFIX (C5h)	
10.74	DMASEQ (C6h)	
10.75	DMAADDR (C7h)	
10.76	PEAK_OC_LIMIT (CDh)	
10.77	PEAK_UC_LIMIT (CEh).	
10.78	VMON_ON (D0h)	
10.79	VMON_OFF (D1h)	89
10.80	COMPPROP (DDh)	90
10.81	COMPINTEG (DEh).	91
10.82	COMPIDFF (DFh)	92
10.83	COMPCFB (E0h)	92
10.84	HS_BUS_CURRENT_SCALE (E3h)	93
10.85	PHASE_CURRENT (E4h)	
10.86	PHASE_TEMPERATURE (E5h)	94
10.87	PEAK_OCUC_COUNT (E9h)	
10.88	SLOW_IOUT_OC_LIMIT (EAh)	95

RENESAS

10.8 10.9 10.9 10.9	90 SLOW_OC_FILT_COUNT (ECh)	96 97
11.	Adaptive Voltage Scaling (AVSBus) Functionality and Operation	99
12.	AVSBus Command Detail	00
12.1	1 TARGET RAIL VOLTAGE (0h)	00
12.2		
12.3	3 RAIL CURRENT (2h)	01
12.4	4 RAIL TEMPERATURE (3h)	01
12.5	5 RESET RAIL VOLTAGE (4h)	02
12.6	6 POWER MODE (5h)	03
12.7	7 AVSBus STATUS (Eh)	04
12.8	3 AVSBus VERSION (Fh)	04
13.	Revision History	05
14.	Package Outline Drawing 1	06



1. Overview

1.1 Typical Applications















Figure 3. ISL68236 8+1 Solution Using Smart Power Stage (ISL99390)

RENESAS

1.2 Internal Block Diagrams



Figure 4. ISL68225 Internal Block Diagram





Figure 5. ISL68236 Internal Block Diagram



1.3 Ordering Information

Part Number (<u>Notes 2, 3</u>)	Part Marking	Junction Temperature (°C)	Tape and Reel (Units) (<u>Note 1</u>)	Package (RoHS Compliant)	Pkg. Dwg. #
ISL68225IRAZ	ISL68225 IRZ	-40 to +125	-	52 Ld 6x6 QFN	L52.6x6A
ISL68225IRAZ-T	ISL68225 IRZ	-40 to +125	4k	52 Ld 6x6 QFN	L52.6x6A
ISL68236IRAZ	ISL68236 IRZ	-40 to +125	-	52 Ld 6x6 QFN	L52.6x6A
ISL68236IRAZ-T	ISL68236 IRZ	-40 to +125	4k	52 Ld 6x6 QFN	L52.6x6A

Notes:

1. See <u>TB347</u> for details about reel specifications.

 These Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J-STD-020.

3. For Moisture Sensitivity Level (MSL), see the ISL68225 and ISL68236 device pages. For more information about MSL, see TB363.

Table 1. Key Differences Between Family of Parts

Part Number	Phase Configuration Output X/Output Y/Output Z	Specification Supported	Package
ISL68225	X+Y ≤ 9	PMBus	QFN 52 Ld, 6x6mm
ISL68236	X+Y ≤ 9	AVSBus/PMBus	QFN 52 Ld, 6x6mm
ISL68239	X+Y+Z ≤ 12	AVSBus/PMBus	QFN 68 Ld, 8x8mm
ISL68229	X+Y+Z ≤ 12	PMBus	QFN 68 Ld, 8x8mm
ISL68227	X ≤ 12	PMBus	QFN 60 Ld, 7x7mm
ISL68226	X+Y+Z ≤ 8	PMBus	QFN 60 Ld, 7x7mm
ISL68224	X+Y+Z ≤ 6	PMBus	QFN 52 Ld, 6x6mm
ISL68233	X+Y ≤ 5	AVSBus/PMBus	QFN 40 Ld, 5x5mm
ISL68223	X+Y ≤ 4	PMBus	QFN 40 Ld, 5x5mm
ISL68222	X+Y ≤ 5	PMBus	QFN 40 Ld, 5x5mm
ISL68221	X+Y+Z ≤ 3	PMBus	QFN 40 Ld, 5x5mm
ISL68220	X+Y ≤ 2	PMBus	QFN 32 Ld, 4x4mm

Table 2. Power Stage Recommendations

Part Number	Rating (A)	Туре	тоит	TREF	REFIN	FAULT#	Package Dwg. #	Pin-to-Pin Compatible	Typically Used With
5.0V PWM Pow	5.0V PWM Power Stage Family								
ISL99227B	60	SPS	Yes	No	Yes	Yes	L32.5x5V	N/A	Phase Doublers: ISL6617A
ISL99360B	60	SPS	Yes	No	Yes	Yes	L32.5x5W	N/A	
3.3V PWM Pow	er Stage Fan	nily					•		
ISL99227	60	SPS	Yes	No	Yes	Yes	L32.5x5V	N/A	Full Digital Controllers:
ISL99360	60	SPS	Yes	No	Yes	Yes	L32.5x5W	N/A	ISL68/69xxx
ISL99380	80	SPS	Yes	No	Yes	No	L39.5x6A	ISL99390	
ISL99390	90	SPS	Yes	No	Yes	No	L39.5x6A	ISL99380	
ISL99392	90	SPS	Yes	Yes	No	Yes	L39.5x6A	N/A	ISL682xx/692xx controllers that support low power state PWM protocol



1.4 Pin Configurations





1.5 Functional Pin Descriptions

See <u>Table 5 on page 33</u> for design layout considerations.

ISL68225 Pin Number	ISL68236 Pin Number	Pin Name	Description			
4, 3, 2, 1, 52, 51, 50, 49, 48	4, 3, 2, 1, 52, 51, 50, 49, 48	PWM[8:0]	Pulse-Width Modulation (PWM) outputs. Connect these pins to the PWM input pins of 3.3V logic-compatible smart power stages, driver ICs, or DrMOS.			
5	5	CFP	Catastrophic fault protection output. This active, high-logic signal can be configured to alert the host to major fault events.			
6	6	nVRHOT	Thermal warning indicator. This open-drain output is pulled low if a sensed over-temperature occurs at the TEMP pins.			
7	-	DNC	Do not connect any signals to these pins.			
8	-	GND	Connect to ground			
9	-	DNC	Do not connect any signals to these pins.			
10	-	GND	Connect to ground.			
-	7	AVS_VDDIO	AVSBus reference voltage input. Leave open if not used.			
-	8	AVS_MDA	AVSBus data input pin. Connect to ground if not used.			
-	9	AVS_SDA	AVSBus data output pin. Leave open if not used.			
-	10	AVS_CLK	Synchronous clock signal input of the AVSBus. Connect to ground if not used.			
12, 11	12, 11	EN[1:0]	Input pin used for enable control of outputs. Connect to ground if not used.			
14, 13	14, 13	PG[1:0]	Open-drain, power-good indicator for outputs.			
15	15	VINSEN	Input voltage sense pin for the V _{IN} supply voltage.			
16	16	VMON	Input voltage sense pin for the driver supply voltage.			
17, 19, 21, 23, 25, 27, 29, 31, 33	17, 19, 21, 23, 25, 27, 29, 31, 33	CSRTN[8:0]	The CS and CSRTN pins are current-sense inputs to the individual phase differential amplifiers. Unused phases should have their respective current-sense inputs grounded. These pins support smart power stage, DCR, and resistor sensing.			
18, 20, 22, 24, 26, 28, 30, 32, 34	18, 20, 22, 24, 26, 28, 30, 32, 34	CS[8:0]	Connection details depend on the current-sense method chosen.			
38, 35	38, 35	RGND[1:0]	Negative differential voltage sense input for the outputs. Connect to the negative remote sensing point. Connect to ground if not used.			
39, 36	39, 36	VSEN[1:0]	Positive differential voltage sense input for the outputs. Connect to the positive remote sensing point. Connect to ground if not used.			
40, 37	40, 37	TEMP[1:0]	Input pin for sensing external temperature measurement at outputs. Supports NTC- based temperature sensing and smart power stage sensing. Connect to ground if not used.			
41	41	CONFIG	Configuration ID selection pin. Attach a resistor from this pin to GND.			
42	42	ADDRESS	SMBus/PMBus address selection pin. Attach a resistor from this pin to GND.			
43	43	VCC	Chip primary bias input. Connect this pin directly to a +3.3V supply with a $1\mu F$ or greater MLCC bypass capacitor.			
44	44	VCCS	Internally generated 1.2V LDO logic supply from VCC. Decouple with a 4.7 μ F or greater MLCC (X5R or better).			
45	45	nPMALERT	Open-drain output pin for alerting the SMBus host.			
46	46	PMSCL	Serial clock signal pin for the SMBus interface.			
47	47	PMSDA	Serial data signal pin for the SMBus interface.			
EPAD	EPAD	GND	The package pad serves as the GND return for all IC functions. Connect directly to the system GND plane with multiple vias.			



2. Specifications

2.1 Absolute Maximum Ratings

Parameter	Pins	Minimum	Maximum	Unit
Input Voltage Range	VCC		+4.3	V
	VCCS		+1.6	V
	VINSEN	GND - 0.3	18	V
	All Other Pins	GND - 0.3	V _{CC} + 0.3	V
ESD Rating		Value		Unit
Human Body Model (Tested per JS-001-2017)	AVS_SDA, AVS_MDA	1		kV
	All Other Pins	2	2	kV
Charged Device Model (Tested per JS-002-2014)	All Pins	75	50	V
Latch-Up (Tested per JESD78E; Class 2, Level A)	All Pins	10	00	mA

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.

2.2 Thermal Information

Thermal Resistance (Typical)	θ _{JA} (°C/W)	θ _{JC} (°C/W)
52 Ld 6x6 QFN Package (<u>Notes 4, 5</u>)	29	2.5

Notes:

4. θ_{JA} is measured in free air with the component mounted on a high-effective thermal conductivity test board with direct attach features. See <u>TB379</u>.

5. For θ_{JC} , the case temperature location is the center of the exposed metal pad on the package underside.

Parameter	Minimum	Maximum	Unit
Maximum Junction Temperature		+150	°C
Maximum Storage Temperature Range	-65	+150	°C
Pb-Free Reflow Profile	S	see <u>TB493</u>	

2.3 Recommended Operating Conditions

Parameter	Minimum	Maximum	Unit
Supply Voltage, V _{CC}	3.135	3.465	V
Junction Temperature	-40	+125	°C
Output Voltage	0	3.05	V



2.4 Electrical Specifications

Recommended operating conditions, V_{CC} = 3.3V, unless otherwise specified. Boldface limits apply across the operating ambient temperature range -40°C to +85°C.

Parameter	Test Conditions	Min (<u>Note 7</u>)	Тур	Max (<u>Note 7</u>)	Unit
V _{CC} Supply Current					•
Nominal Supply Current	V_{CC} = 3.3 V_{DC} ; ENx = V_{IH} , all rails and phases operating, f_{SW} = 600kHz		58		mA
Shutdown Supply Current	V_{CC} = 3.3 V_{DC} ; ENx = 0V, no switching		8		mA
VCCS LDO Supply					•
Output Voltage			1.22		V
Maximum Current Capability	Excluding internal load		20		mA
Power-On Reset (POR)		•			
V _{CC} Brownout Threshold			2.95		V
VCCS Rising POR Threshold			1		V
VCCS Falling POR Threshold			0.9		V
Enable Input High Level		2.0			V
Enable Input Low Level				0.8	V
Configurations Stored in Memory					
Number of Configuration Write Slots		28			
Number of Unique Configurations Stored		16			
POR to Initialization	1				
POR to Initialization Complete Time			15		ms
Output Voltage Characteristics	1				
System Accuracy	Note 6, closed loop V _{OUT} set-point = 1.00V to 3.05V	-0.5		0.5	%
	Note 6, closed loop V _{OUT} set-point = 0.8V to 0.999V	-5		5	mV
	Note 6, closed loop V _{OUT} set-point = 0.25V to 0.799V	-8		+8	mV
Voltage Sense Amplifier					
Open Sense Current	Only at VSEN open detection during initialization period		220		μA
Input Impedance (VSEN - RGND)			140		kΩ
Maximum Common-Mode Input			V _{CC} - 0.2		V
Differential Input Range (VSEN - RGND)				3.05	V
Output Current-Sense and Overcurrent Pr	otection				
Current-Sense Accuracy	SPS configuration	-1		1	%
Average Overcurrent Threshold Resolution			0.1		А
Cycle-by-Cycle Current Limiting Threshold Resolution			0.4		A
Digital Droop	-				
Droop Resolution			0.01		mV/A
Oscillators		1			
Accuracy of Switching Frequency Setting			±2		%
Switching Frequency Range		0.2		2.0	MHz



Recommended operating conditions, V_{CC} = 3.3V, unless otherwise specified. Boldface limits apply across the operating ambient temperature range -40°C to +85°C. (Continued)

Parameter	Test Conditions	Min (<u>Note 7</u>)	Тур	Max (<u>Note 7</u>)	Unit
Soft-Start Rate and V _{OUT} Transition Rate				•	
Minimum Soft-Start Ramp Rate	Programmable minimum rate		0.01		mV/μs
Maximum Soft-Start Ramp Rate	Programmable maximum rate		100		mV/µs
Soft-Start Ramp Rate Accuracy			±2		%
Minimum V _{OUT} Transition Rate			0.01		mV/µs
Maximum Fast V _{OUT} Transition Rate			100		mV/µs
V _{OUT} transition Rate Accuracy		-4		4	%
PWM Output (PWM[8:0])				1	
PWMx Output High Level	I _{OUT} = 4mA	V _{CC} - 0.4			V
PWMx Output Low Level	I _{OUT} = 4mA			0.4	V
PWM Tri-State Leakage (pin forced high)	V _{PWM} = V _{CC}			1	μA
PWM Tri-State Leakage (pin forced low)	V _{PWM} = 0V	-1			μA
Thermal Monitoring and Protection					
Temperature Sensor Range		-50		150	°C
Temperature Sensor Accuracy	SPS configuration		±4.5		%
nVRHOT Output Low Impedance			9		Ω
Power-Good and Protection Monitors				1	
PG Output Low Voltage	I _{OUT} = 4mA load			0.2	V
PG Leakage Current	With a pull-up resistor externally connected to VCC		5		μA
Overvoltage Protection Threshold Resolution			1		mV
Undervoltage Protection Threshold Resolution			1		mV
Input Voltage-Sense and Catastrophic Fail	ure Protection (CFP) Output				
Input Voltage Accuracy	VINSEN to ADC accuracy		±2.5		%
Input Overvoltage Threshold Resolution			16		mV
CFP Output High Voltage	I _{OUT} = 8mA	V _{CC} - 0.4			V
CFP Output Low Voltage	I _{OUT} = 8mA			0.4	V
AVSBus					
AVSBus VDDIO Input Voltage Range		0.9		3.63	
AVSBus CLK, MDA Input High Level		0.6* V _{DDIO}			V
AVSBus CLK, MDA Input Low Level				0.4 * V _{DDIO}	V
AVSBus SDA Output High Level		0.8*V _{DDIO}			V
AVSBus SDA Output Low Level				0.2*V _{DDIO}	V
AVSBus CLK Frequency Range		5		50	MHz



Recommended operating conditions, V_{CC} = 3.3V, unless otherwise specified. Boldface limits apply across the operating ambient temperature range -40°C to +85°C. (Continued)

Parameter	Test Conditions	Min (<u>Note 7</u>)	Тур	Max (<u>Note 7</u>)	Unit		
SMBus/PMBus	SMBus/PMBus						
nPMALERT, PMSDA Output Low Level	I _{OUT} = 20mA			0.4	V		
PMSCL, PMSDA Input High Level		1.35			V		
PMSCL, PMSDA Input Low Level				0.8	V		
PMSCL, PMSDA Input Hysteresis			80		mV		
PMSCL Frequency Range		0.01		2.00	MHz		

Notes:

6. These parts are designed and adjusted for accuracy with all errors in the voltage loop included. Verified by design and/or characterization.

7. Compliance to datasheet limits is assured by one or more methods: production test, characterization, and/or design.



3. Initializing the Device

3.1 Power-On Reset (POR)

Initialization begins after V_{CC} crosses its rising POR threshold. When POR conditions are met, basic digital subsystem integrity checks begin. During this process, the controller starts the telemetry subsystem, configures its PMBus address according to the ADDRESS pin resistor value, loads the selected user configuration from NVM as indicated by the CONFIG pin resistor value, checks fault status, and prepares for regulation. The PWM pins are held in tri-state until the device is commanded to regulate. Figure 6 shows the device initialization sequence.



Figure 6. Simplified PMBus Initialization Timing Diagram



3.2 Selecting the PMBus Address

A resistor reader selects the PMBus slave address. The ADDRESS pin reads the value of a resistor connected to GND to determine the PMBus address to use during host communication. Table 3 shows the $R_{ADDRESS}$ values to specify the PMBus slave addresses (7-bit).

R Value (Ω)	PMBus Address	R Value (Ω)	PMBus Address
0	60	5230	51
162	61	5900	52
316	62	6650	53
487	63	7500	54
681	64	8450	55
887	65	9530	56
1130	66	10700	57
1370	67	12100	58
1650	45	13700	59
1960	46	15400	5A
2320	47	17400	5B
2670	4C	19600	5C
3090	4D	22100	5D
3570	4E	24300	5E
4120	4F	27400	5F
4640	50	30100	68

 Table 3.
 Resistor Value to PMBus Address Map

3.3 Selecting the User Configurations

At power-up, a user configuration is loaded for operation. The CONFIG pin reads the value of a resistor connected to GND to determine which user configuration is loaded. The ISL68225 and ISL68236 support 16 distinct configuration identifiers. Table 4 provides the R_{CONFIG} value corresponding to each configuration identifier. A total of 28 one-time programmable non-volatile memory locations are available to store new user configurations or overwrite existing ones. With this flexibility, all 16 unique configurations can be written with 12 available overwrites, one configuration ID can be written up to 28 times, or any combination of configuration ID can be written up to 28 times, or any combination for a given configuration ID can be loaded. When all 28 memory locations have been written, the ISL68225 and ISL68236 no longer accept attempts to write to NVM. PowerNavigator provides a simple interface to store and load configurations.

Table 4.	Resistor Value to CONFIG ID Ma	ар
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R Value (Ω)	Configuration ID	R Value (Ω)	Configuration ID
0	0	1650	8
162	1	1960	9
316	2	2320	10
487	3	2670	11
681	4	3090	12
887	5	3570	13
1130	6	4120	14
1370	7	4640	15



3.4 Configuring the Device

Configure the ISL68225 and ISL68236 to generate a configuration file using PowerNavigator and either directly load to the device RAM or program to the device NVM. During device initialization, the IC attempts to load a configuration from NVM. If no configuration is found, the device remains in a wait state with the PWM pins tri-stated. The device ignores attempts to enable and waits until a configuration is directly loaded using PowerNavigator. The IC features and functions described in this datasheet are all configured using PowerNavigator. The datasheet provides a fundamental understanding of device behavior and design information. PowerNavigator provides additional detail about the configuration process.



4. Operating the Device

After the ISL68225 and ISL68236 initialize and a configuration is loaded, they are ready for operation.

The ISL68225 and ISL68236 have several performance enhancing features that enable them to meet the most stringent voltage regulation and efficiency demands. The synthetic current modulator provides excellent transient response to support the latest generation of ASICs and CPUs. Automatic phase dropping, diode emulation, and PFM operation improve efficiency across the load range. The ISL68225 and ISL68236 support Smart Power Stage (SPS) current sense and DCR/resistor current sense to enable optimal design. The devices also support a full complement of high-resolution telemetry, including per-phase temperature sense when paired with select Renesas SPS devices. The following sections provide more detail about using these features.

4.1 Input Voltage Sensing

Input voltage is monitored using the VINSEN pin. Connect the VINSEN pin as shown in Figure 7.



Figure 7. Input Voltage Sense Configuration

Input voltage is monitored continuously, and regulation is stopped anytime the sensed input voltage falls outside the boundaries established by configuration settings associated with the parameters V_{IN} ON, V_{IN} OFF, V_{IN} Overvoltage Fault Limit, and V_{IN} Undervoltage Fault Limit.

4.2 Lossless Input Current and Power Sensing

Input current telemetry is provided per rail using an input current synthesizer. By using the ability of the ISL68225 and ISL68236 to precisely determine their operational conditions, the input current can be synthesized to a high degree of accuracy without the need for a lossy sense resistor. With a precise knowledge of input current and voltage, the input power can be computed.

4.3 VMON Voltage Sensing

The VMON input pin provides a secondary input voltage sense with several selectable voltage ranges. The VMON input pin can be used to inhibit rail operation when the sensed voltage falls outside the boundary established by the configuration settings that are associated with the parameters VMON_ON and VMON_OFF. If a rail is prevented from operating due to a VMON excursion, the rail restarts if the sensed voltage returns to the specified range. Use of this feature is optional for each rail. A typical use case for this voltage sensing feature is monitoring the bias supply voltage associated with the power stages and preventing operation if this voltage is below the configured range. Connection of the VMON pin for sensing the 5V SPS bias voltage is shown in Figure 8.



Figure 8. VMON Configuration



4.4 Enabling and Soft-Starting the Device

The ISL68225 and ISL68236 outputs can be enabled using the enable pin or PMBus. Enable method selection is configured in PowerNavigator on a per-rail basis. The ISL68225 and ISL68236 begin their soft-start sequence when they are commanded to regulate an output. Soft-start moves V_{OUT} smoothly to the programmed VOUT_COMMAND. Soft-start timing is programmed using the <u>TON_DELAY (60h)</u> and <u>TON_RISE (61h)</u> PMBus commands.

If a pre-existing voltage bias exists on the output, the PWM signals are held in tri-state until the soft-start ramp reaches the prebias level. The tri-state prevents the converter from sinking current and pulling the prebias down. No special configuration is required to enable this operation.

4.5 Disabling the Device

Similar to the enabling process, outputs can be disabled using the enable pin or PMBus on a per-rail basis. The ISL68225 and ISL68236 can be configured to disable in two ways:

- Immediate OFF: Immediately ceases regulation and tri-states PWM pins.
- **Soft OFF**: Actively ramps the output voltage down to 0V before ceasing activity as programmed in <u>TOFF_DELAY (64h)</u> and <u>TOFF_FALL (65h)</u> PMBus commands.

4.6 Phase Configuration and Automatic Phase Dropping

The ISL68225 and ISL68236 support two regulated outputs that control their nine phases. Each rail is capable of controlling up to nine phases, but the rails can be configured for fewer phases. Unused phases should have their CS and CSRTN pins grounded.

The ISL68225 and ISL68236 support Automatic Phase Dropping (APD) to optimize efficiency across the load range. <u>Figure 9</u> shows the typical characteristics of efficiency vs load current as the phase count is varied. The diagram shows that for a typical multiphase system, optimal efficiency is achieved by using fewer phases as the load current decreases.



Figure 9. Efficiency vs Phase Number

The ISL68225 and ISL68236 continuously monitor output current, and if APD is enabled, the devices drop or add phases from use as the load current varies.

Phases are dropped one at a time with a user-programmed delay between drop events. For example, if the delay is set to 1ms, nine phases are active, and the load suddenly drops to a level needing only one phase; the ISL68225 and ISL68236 begin by dropping a single phase after 1ms. An additional phase is dropped each millisecond until only one phase remains active. On Rail 0, phases are dropped beginning with the highest assigned phase. On Rail 1, phases are dropped beginning with the lowest assigned phase.

Phases are automatically returned to service when load conditions require more phases. The phases are returned to service in the opposite order they were dropped. Conditions that result in phase adding include increased load

current, rapid change sensed on the output voltage, and V_{OUT} transition events. When rapid change is sensed on the output voltage, the Fast Phase Add function prepares all dropped phases for activation so there is no delay if all phases are needed to support a load transient.

Any command to change the output voltage set point uses all phases, including V_{OUT} transition events. After the output voltage change is complete, phases begin dropping as configured.

To ensure dropped phases have sufficient bootstrap capacitor charge to turn on the high-side MOSFET after a long period of inactivity, a bootstrap refresh function periodically turns on the low-side MOSFET of each dropped phase to refresh the bootstrap capacitor.

To produce the most optimal efficiency across a wide range of output loading, the modulator supports automatic dropping or adding of phases and diode emulation (in a single-phase state). Use of APD and diode emulation are optional. If automatic phase dropping is enabled, the number of active phases at any time is determined solely by load current.

4.7 Diode Emulation and PFM Operation

As described in <u>Phase Configuration and Automatic Phase Dropping</u>, the ISL68225 and ISL68236 support APD to optimize phase usage as load demand decreases. When the regulator drops to 1-phase operation, it supports diode emulation and Pulse Frequency Modulation (PFM) operation to further maximize efficiency performance. Traditionally, use of such efficiency boosting techniques have come at the expense of transient response, but the ISL68225 and ISL68236 are able to meet all transient demands directly from diode emulation/PFM operation.

Diode emulation and PFM operation are supported when a single phase is active. If constant frequency operation is needed at light loads, the feature can be disabled. If enabled, the low-side MOSFET conducts when the current is flowing from source-to-drain and does not allow a reverse current, emulating an ideal diode. As Figure 10 shows, when the inductor current is positive, the LGATE is held on and allows current to flow in the low resistance channel of the LFET. When current reaches zero, the LFET is turned off to prevent a reverse current in the inductor. The controller modulates the LFET state through the PWM pin of the respective regulator channel by tri-stating the PWM when the load current reaches zero, which commands the MOSFET driver to turn off both the HFET and LFET.



Figure 10. Diode Emulation PWM Signaling

In single-phase diode emulation operation, the ISL68225 and ISL68236 deliver inductor current pulses with a user-programmed pulse width. By programming the pulse width, the output voltage ripple can be tuned to meet expectations for any system type. Pulse frequency is then modulated to maintain output voltage regulation as shown in <u>Figure 11</u>. The transition from single phase PFM to multiphase constant frequency operation is managed seamlessly by the ICs.

Load Current Inductor Current

Figure 11. Single Phase Light Load PFM Operation



4.8 Diode Braking

Applications that support loads with large transient current demands often have significant output voltage overshoot when the load current demand drops suddenly. In some cases, diode braking may allow overshoot reduction at the expense of thermal dissipation in the low-side MOSFET.

4.9 Switching Frequency

Switching frequency is independently programmable on each rail from 200kHz to 2MHz.

4.10 Output Current Sensing

The ISL68225 and ISL68236 support DCR, resistor, and smart power stage current sensing. Use the differential input CS and CSRTN pins to connect to the various sense elements.

4.10.1 SPS Current Sensing

In applications using Smart Power Stage (SPS), the SPS IMON output is connected to the corresponding ISL68225 and ISL68236 CSn input. The CSRTNn pins are connected to the SPS current sense reference voltage. For connection details, see the typical application diagrams shown in <u>Figures 1</u>, <u>2</u>, and <u>3</u>.

4.10.2 Inductor DCR Sensing

Inductor windings have a resistive component (DCR) that drops a voltage proportional to the inductor current. <u>Figure 12</u> shows that the DCR is treated as a lumped element with one terminal inaccessible for measurement. Fortunately, a simple R-C network as shown in <u>Figure 12</u> can reproduce the hidden DCR voltage. By matching the R-C time constant to the L divided by DCR time constant, it is possible to precisely recreate the DCR voltage across the capacitor, so that VDCR(t) = VC(t), preserving even the switching frequency characteristic of the DCR voltage.



Figure 12. DCR Sensing Configuration

Modern inductors often have such low DCR values that the resulting signal is <10mV. To avoid noise problems, care must be taken in the Printed Circuit Board (PCB) layout to properly place the R-C components and route the differential lines between controller and inductor. Figure 12 shows one PCB design method that places the R component near the inductor VPHASE and the C component very close to the IC pins. The design method maintains isolation of the noisy VPHASE node and maximizes filtering near the IC. Route the lines as a pair on a single layer directly to the controller. Avoid routing the pair near any switching signals such as Phase and PWM. This is the method used by Renesas on evaluation board designs. **Note:** The R component should be 0603 or greater size to limit the effects of voltage coefficient of resistance in the resistor.

Because the DCR is actually the resistance of a metal winding, the DCR value increases with rising temperature. The increase must be compensated or the sensed (and reported) current increases with temperature. To compensate the temperature effect, the ISL68225 and ISL68236 provide temperature sensing options and an internal methodology to apply the correction.



4.10.3 Resistive Sensing

For more accurate current sensing, a dedicated current-sense resistor, R_{SENSE} , in series with each output inductor, can serve as the current-sense element. However, this technique reduces the overall converter efficiency due to the additional power loss on the current-sense element, R_{SENSE} .

A current-sensing resistor has a distributed parasitic inductance known as Equivalent Series Inductance (ESL), which is typically less than 4nH. Consider the ESL as a separate lumped quantity, as shown in Figure 13. The phase current, I_L , flowing through the inductor, also passes through the ESL. Similar to DCR sensing described in Inductor DCR Sensing, a simple R-C network across the current-sense resistor extracts the R_{SENSE} voltage. Match the ESL/R_{SENSE} time constant to the R-C time constant.



Figure 13. Sense Resistor in Series with Inductor

<u>Figure 14</u> shows the sensed waveforms with and without matching RC when using resistive sense. PCB layout for resistive sense should follow the guidance described for DCR sense.



Figure 14. Voltage Across R with and without RC



4.10.4 L/DCR or ESL/R_{SEN} Matching

Assuming the compensator design is correct, Figure 15 shows the expected load transient response waveforms if L/DCR or ESL/R_{SEN} matches the R-C time constant for a droop application. When the load current I_{OUT} has a square change, the output voltage V_{OUT} also has a square response, except for the potential overshoot at load release. However, there is always some uncertainty in the true parameter values involved in the time constant matching, so fine-tuning is generally required.



Figure 15. Desired Load Transient Response Waveforms

If the R-C time constant is too large or too small, $V_C(t)$ does not accurately represent real-time $I_{OUT}(t)$ and worsens the transient response. Figure 16 shows the load transient response when the R-C time constant is too small. In this condition, V_{OUT} sags excessively on load insertion and can create a system failure or early overcurrent trip.



Figure 16. Load Transient Response when R-C Time Constant is Too Small

<u>Figure 17</u> shows the transient response when the R-C time constant is too large. V_{OUT} is sluggish in drooping to its final value. Use these general guides if fine-tuning is needed.



Figure 17. Load Transient Response when R-C Time Constant is Too Large



5. Temperature Sensing

The ISL68225 and ISL68236 monitor internal die temperature and support external per-rail SPS or NTC resistor temperature sense using the TEMPn pins. The controllers also provide per-phase temperature sense using the CS and CSRTN pins when paired with select Renesas SPS devices.

5.1 SPS Temperature Sensing

The ISL68225 and ISL68236 can be configured to sense SPS temperature on a per-rail or per-phase basis. To configure for per-rail temperature sense, connect the TOUT/FLT pin of each SPS in the rail together and tie the net to the ISL68225/ISL68236 TEMPn pin. Select SPS devices also have current sense reference voltage outputs (TREF) that are proportional to temperature. The ISL68225 and ISL68236 can be configured to accept this signal and report individual phase temperature. When configured for per-phase temperature sense, the SPS TOUT/FLT pins should remain connected to the ISL68225/ISL68236 TEMPn pin, because the SPS devices report internal fault conditions through the TOUT/FLT pin. See the typical application diagrams (starting with Figure 1 on page 6) for a detailed connection overview of per-rail and-per phase temperature sense.

5.2 NTC Temperature Sensing

NTC temperature sensing is used in conjunction with inductor DCR output current sensing to sense the inductor temperature. In this configuration, the specified NTC is connected to the IC as shown in <u>Figure 18</u>. To avoid noise problems, route the PCB traces leading to the NTC differentially and keep away from noise sources. **Note**: Use the component values shown.



Figure 18. NTC Temperature Sense Connection

When automatic phase dropping is used in a multiphase design, position the NTC close to the phase that runs in single-phase operation. For Rail 0, the correct phase is the lowest phase number assigned to the rail. For Rail 1, the correct phase is the highest phase number assigned as shown in Figure 19 on page 28.





Figure 19. NTC Placement

5.3 Temperature Compensation

The ISL68225 and ISL68236 support temperature compensation to improve the DCR current sense accuracy. Copper wire used to form inductors has a resistivity temperature coefficient of 0.39%/°C. Because the voltage across the inductor is sensed for the output current information, the sensed signal has the same positive temperature coefficient as the inductor DCR.

Compensating current sense for temperature variation requires that the current-sensing element temperature and temperature coefficient are known. Although the temperature coefficient is easily obtained, actual current-sense element temperature is difficult to measure directly. Instead, an NTC temperature sensor placed near an inductor is measured, and the compensation is applied based on this sensed temperature.

The sensed temperature and the actual temperature are different because the temperature sensor is not perfectly coupled to the inductor winding. To accommodate this difference, the ISL68225 and ISL68236 allow you to fine-tune temperature compensation for optimal current sense accuracy. For applications requiring the highest current sense accuracy, use SPS current sense.



6. Fault Monitoring and Protection

The ISL68225 and ISL68236 include an extensive fault management system that integrates with high performance host controllers, supporting unprecedented remote system management and debugging capability. If a fault condition occurs, the IC deasserts the PG pin associated with the faulted rail and alerts the host using the PMAlert pin. You can optionally configure the Catastrophic Failure Protection (CFP) to assert on select faults for additional protection measures at the system level. The ISL68225 and ISL68236 also provide Black Box, a recorder with extensive fault logging to support system level debug.

Fault controls are independently enabled and associated fault responses are user configurable. Response type is independently configurable by fault type. Response types supported are:

- Alert only: The rail continues to operate.
- Shut down immediately: The rail is latched off until commanded on.
- Shut down and retry with variable retry delay: The rail attempts to retry indefinitely until the condition clears or the rail is commanded off.

When a fault condition has been declared, clear the fault by issuing a <u>CLEAR_FAULTS (03h)</u> command or by cycling the EN pin of the faulted rail.

6.1 Power-Good Signals

The PG pins are open-drain, power-good outputs that indicate completion of the soft-start sequence and output voltage of the associated rail within the expected regulation range. If a fault occurs, the PG pin of the associated rail is pulled low. PG is also pulled low immediately on a rail disable.

6.2 Overvoltage/Undervoltage Protection

Output voltage is measured at the load sensing points differentially for regulation, and the same measurement is used for OVP and UVP. The fault thresholds are set using PMBus commands. Figure 20 shows a simplified OVP/UVP block diagram. The output voltage comparisons are done in the digital domain.



Figure 20. OVP, UVP Comparators

The device responds to an output overvoltage condition by disabling the output, declaring a fault, setting the PMALERT pin, pulling the PG pin low, and pulsing the LFET until the output voltage drops below the threshold. Similarly, the device responds to an output undervoltage condition by disabling the output, declaring a fault, setting the PMALERT pin, and pulling the PG pin low. The output does not restart until the EN pin is cycled (unless the device is configured to retry).

The ISL68225 and ISL68236 also feature open pin sensing protection to detect an open of the output voltage sensing circuit. When this condition is detected, controller operation is suspended.



6.3 Output Overcurrent Protection

The ISL68225 and ISL68236 provide a comprehensive overcurrent protection scheme that monitors the total output current, peak phase current, and the valley phase current. The scheme allows you to eliminate inductor saturation and limit the total output current. The ISL68225 and ISL68236 support shutdown and retry response types for OC faults. The response configuration applies to all output current fault mechanisms such as phase peak overcurrent and total output overcurrent.

Figure 21 shows the block diagram of the output overcurrent protection scheme.



Figure 21. OCP Functional Diagram

Phases are protected from both overcurrent and undercurrent using a pulse-by-pulse scheme that acts instantly on a PWM signal if a detected phase current reaches its threshold. Thresholds for overcurrent and undercurrent allow you to precisely limit phase currents so the inductors never saturate. Phase current limiting behavior can be configured to either shut down the device after a user-determined number of consecutive events or continue indefinitely. If configured to continue indefinitely, the converter behaves much like a current source. Figures 22 and 23 show per-phase current limiting when the device is configured to shut down after a user-determined number of consecutive events.







In addition to phase based current limiting, the ISL68225 and ISL68236 support total output current limits that have user-adjustable response delay. The two sum current limits, fast and slow, allow you to permit high maximum output current for a shorter period of time and lower output current for a longer period. The response delay for the limiting mechanisms is also adjustable. These mechanisms do not restrict the maximum output current has exceeded a threshold for the response delay time. For example, suppose the device is configured with a Fast Sum OC limit of 250A, a response delay of 50µs, and a shutdown response type. Next, suppose a 300A load is placed on the regulator. 300A is supplied to the load for 50µs, and the device shuts down as shown in Figure 24 on page 31.





6.4 Smart Power Stage OC Fault Detect

Renesas Smart Power Stage (SPS) devices output a large signal on their IMON lines if peak current exceeds their preprogrammed threshold; for more details about this functionality, see the relevant SPS datasheet. The ISL68225 and ISL68236 detect this fault flag by sensing signals that exceed the current-sense ADC full scale range and immediately shut down.

SPS devices that conform to the industry common footprint, such as the ISL99380, do not use the IOUT pin for signaling overcurrent faults. All faults are signaled using their TOUT/FLT pins, and the ISL68225 and ISL68236 provide a detector on each TEMP pin to support this method.

6.5 Thermal Protection and nVRHOT

The ISL68225 and ISL68236 support a comprehensive scheme for thermal alerting and protection. Regardless of temperature sense method, the devices support over-temperature or under-temperature faults in addition to over-temperature warning. When configured for per phase temperature telemetry, temperature faults are triggered based on the hottest reported phase. For example, if a 3-phase rail with an over-temperature threshold of +110°C reports phase temperatures of +100°C, +102°C, and +111°C, the devices declare a fault because the hottest phase at +111°C exceeds the +110°C fault threshold. When configured for per-phase temperature sense, the SPS TOUT/FLT pins should remain connected to the ISL68225/ISL68236 TEMP pins.

IC die temperature is monitored to support telemetry and thermal shutdown. Shutdown occurs at approximately +130°C.

The nVRHOT pin is used at the system level to inform the powered device to reduce its power consumption. nVRHOT is an open-drain output; an external pull-up resistor is required. This signal is valid only after the controller is enabled. nVRHOT is pulled low when the sensed temperature for any rail reaches the PMBus OT_WARN threshold, providing the powered device with an advance warning of the thermal status of the IC.

Figure 25 shows the behavior of nVRHOT and an over-temperature fault shutdown.



Figure 25. nVRHOT and Over-Temperature Shutdown

6.6 Catastrophic Failure Protection

The CFP pin supports Catastrophic Failure Protection (CFP) functionality. The pin can be configured to activate if a catastrophic fault detection occurs. The function is typically used to immediately disable the input supply to protect the entire system. The CFP function can be configured to respond to output overvoltage, input overvoltage, and/or output overcurrent faults.



6.7 Black Box Recorder

Black Box is a powerful diagnostic tool that captures all telemetry and status information when any fault occurs. The ISL68225 and ISL68236 continuously monitor all rail and phase information along with the time duration that the rail has been regulating, and the tool captures that data when a fault is registered. The tool reports the first fault bit that occurred to cause the shutdown. This diagnostic data is stored in RAM, and Black Box can be configured to additionally write to NVM for retrieval when the system loses input power as a fault occurs. The RAM record is updated every time a fault occurs. Black Box can write to NVM up to 10 times and provides an option to limit NVM writing to once per power cycle to avoid filling up the available NVM space inadvertently.



7. Layout and Design Considerations

The following layout and design strategies help minimize noise coupling and the impact of board parasitic impedances on converter performance, and they optimize the heat dissipating capabilities of the Printed Circuit Board (PCB). Follow these practices during the layout and design process.

7.1 Pin Noise Sensitivity, Design, and Layout Consideration

<u>Table 5</u> provides general guidance on best practices related to pin noise sensitivity. Use of good engineering judgment is required to implement designs based on criteria specific to the situation.

Pin Name	Noise Sensitive	Description
VINSEN	Yes	Filter VINSEN with 100nF capacitor when sensing VIN directly. Use 10nF when using a resistor divider.
RGNDx VSENx	Yes	Treat each of the remote voltage sense pairs as differential signals in the PCB layout. Route them side by side on the same layer. Do not route them in proximity to noisy signals like PWM or Phase. Place a 3.3nF capacitor across the signals directly at the pins on the top layer.
AVS_CLK, AVS_SDA, AVS_MDA	Yes	This is a high speed bus that should be routed carefully. Provide 20 mils of spacing within SDA, MDA, and CLK, and more than 30 mils to all other signals. Tie CLK and MDA to ground when unused.
PGx	No	Open-drain. Avoid setting its pull-up higher than VCC. Tie it to ground when not used.
PMSCL, PMSDA, nPMALERT	Yes	50kHz to 2MHz signals should pair up with nPMALERT and be routed carefully between devices and back to the host. Provide 20 mils of spacing within PMSDA, nPMALERT, and PMSCL, and more than 30 mils to all other signals. See the <u>Layout and Design Considerations</u> and place proper terminated (pull-up) resistance for impedance matching. Tie to ground when not used. Pull up to 3.3V max.
TEMPx	Yes	While using SPS, place a filter capacitor no greater than 500pF between each TEMP pin and ground near the IC. While using NTC, place a 47pF capacitor and a 22k resistor near the IC and route a differential signal pair from there to the remote NTC. Use Murata NCP15XH103J03RC (5% tolerance) or NCP15XH103F03RC (1% tolerance). Tie to ground if not used.
nVRHOT	No	Open drain. Avoid setting its pull-up rail higher than VCC.
VCC	Yes	Place a 1µF MLCC decoupling capacitor (X5R or better) directly at the pin.
VCCS	Yes	Place a 4.7µF MLCC decoupling capacitor (X5R or better) directly at the pin.
PWMx	No	Avoid routing near noise sensitive analog lines such as current sense or voltage sense. Leave floating if not used.
CSx CSRTNx	Yes	Treat each of the current sense pairs as differential signals in the PCB layout. Route them side by side on the same layer. Do not route them in close proximity to noisy signals like PWM or Phase. Proper routing of current sense is perhaps the most critical of all the layout tasks. Place the R-C filter between CSx and CSRTNx at the controller for SPS configuration.
GND	Yes	This EPAD is the ground for all IC signals. Use four or more vias to directly connect the EPAD to the ground plane. Never use only a single via or a 0Ω resistor connection to the power ground plane. Split ground planes are not advised.
General Comments		The layer next to the top or bottom layer should be a ground layer. The signal layers should be sandwiched between the ground layers if possible.

 Table 5.
 Pin Design and/or Layout Consideration



8. PMBus Protocol

The PMBus Protocol includes the Send Byte, the Write Byte/Word, Read Byte/Word, Group Command, and Alert Response Address protocols.

PMBus Protocol Legend				
S: Start Condition				
A: Acknowledge ("0")				
N: Not Acknowledge ("1")				
W: Write ("0")				
RS: Repeated Start Condition				
R: Read ("1")				
PEC: Packet Error Checking				
P: Stop Condition				
Acknowledge or DATA from Slave, Controller				

8.1 Send Byte Protocol



Example command: 03h Clear Faults

(This clears all of the bits in Status Byte for the selected rail)



8.2 Write Byte/Word Protocol



Example command: 21h VOUT_COMMAND

Figure 27. Write Byte/Word Protocol



8.3 Read Byte/Word Protocol



Example command: 8B READ_VOUT (Two words, read voltage of the selected rail).

Note: The STOP (P) bit is NOT allowed before the repeated START condition when reading contents of a register.

Figure 28. Read Byte/Word Protocol

8.4 Group Command Protocol



Note: No more than one command can be sent to the same Address

Figure 29. Group Command Protocol

8.5 Alert Response Address



Figure 30. Alert Response Address (ARA, 0001_1001, 25h) for SMBus and PMBus, not used for I²C



9. PMBus Command Summary

Code	Command Name	Description	Туре	Data Format	Default Value	Default Setting
00h	<u>PAGE (00h)</u>	Rail selector	R/W	Bit	00h	Page 0
01h	OPERATION (01h)	Enable/disable, V _{OUT} source	R/W	Bit	08h	Immediate off, Act on fault
02h	ON_OFF_CONFIG (02h)	On/off configuration settings	R/W	Bit	17h	ENABLE pin control, active high, immediate off
03h	CLEAR_FAULTS (03h)	Clears all fault bits in all registers and releases the nPMALERT pin	Write	N/A	N/A	N/A
04h	<u>PHASE (04h)</u>	Phase selector	R/W	Direct	00h	Phase 0
05h	PAGE_PLUS_WRITE (05h)	Allows page and command write in single transaction	Block Write	Bit	N/A	N/A
06h	PAGE_PLUS_READ (06h)	Allows page and command read in single transaction	Block Write/read /process call	Bit	N/A	N/A
10h	WRITE_PROTECT (10h)	Write protection to sets of commands	R/W	Bit	00h	No write protection
19h	<u>CAPABILITY (19h)</u>	Reports PMBus capability	Read	Bit	ISL68225: D0h ISL68236: D4h	See detail
1Bh	SMBALERT_MASK (1Bh)	Mask status bits from SMBALERT signal	Block R/W	Bit	00h	No bits masked
20h	VOUT_MODE (20h)	Defines format for output voltage related commands	Read	Bit	40h	Direct format
21h	VOUT_COMMAND (21h)	Output voltage set by PMBus	R/W	Direct	0384h	900mV
22h	VOUT_TRIM (22h)	Applies trim voltage to V _{OUT} set-point	R/W	Direct	0000h	0mV
23h	VOUT_CAL_OFFSET (23h)	Applies offset voltage to V _{OUT} set-point	R/W	Direct	0000h	0mV
24h	VOUT_MAX (24h)	Absolute maximum voltage setting	R/W	Direct	0BEAh	3050mV
25h	VOUT_MARGIN_HIGH (25h)	Sets voltage target during margin high	R/W	Direct	03B1	945mV
26h	VOUT_MARGIN_LOW (26h)	Sets voltage target during margin low	R/W	Direct	0357	855mV
27h	VOUT_TRANSITION_RATE (27h)	Slew rate setting for V _{OUT} ramp	R/W	Direct	09C4h	25mV/µs
28h	VOUT_DROOP (28h)	Sets the load-line (V/I slope) resistance for the output	R/W	Direct	0000h	0μV/A
2Bh	VOUT_MIN (2Bh)	Absolute minimum voltage setting	R/W	Direct	0000h	0mV
33h	FREQUENCY_SWITCH (33h)	Sets PWM switching frequency	R/W	Direct	0258h	600kHz
34h	POWER_MODE (34h)	Sets the power conversion mode	R/W	Bit	03h	Maximum power
35h	<u>VIN_ON (35h)</u>	Sets the V _{IN} startup threshold	R/W	Direct	02BCh	7000mV
36h	VIN_OFF (36h)	Sets the V _{IN} shutdown threshold	R/W	Direct	01F4h	5000mV


Code	Command Name	Description	Туре	Data Format	Default Value	Default Setting
40h	VOUT_OV_FAULT_LIMIT (40h)	Sets the V _{OUT} OV fault limit while disabled	R/W	Direct	0C1Ch	3100mV
41h	VOUT_OV_FAULT_RESPONSE (41h)	Configures the V _{OUT} OV fault response	R/W	Bit	84h	Latch off
44h	VOUT_UV_FAULT_LIMIT (44h)	Sets the V _{OUT} UV fault limit	R/W	Direct	0000h	0V
45h	VOUT_UV_FAULT_RESPONSE (45h)	Configures the V _{OUT} UV fault response	R/W	Bit	84h	Latch off
46h	IOUT_OC_FAULT_LIMIT (46h)	Sets the I _{OUT} OC fault limit	R/W	Direct	12Ch	30A
47h	IOUT_OC_FAULT_RESPONSE (47h)	Configures the I _{OUT} OC fault response	R/W	Bit	C4h	Latch off
4Fh	OT_FAULT_LIMIT (4Fh)	Sets the OT fault limit	R/W	Direct	007Dh	125°C
50h	OT_FAULT_RESPONSE (50h)	Configures the OT fault response	R/W	Bit	84h	Latch off
51h	OT_WARN_LIMIT (51h)	Sets the OT warning limit	R/W	Direct	006Eh	110°C
53h	UT_FAULT_LIMIT (53h)	Sets the UT fault limit	R/W	Direct	FFD8h	-40°C
54h	UT_FAULT_RESPONSE (54h)	Configures the UT fault response	R/W	Bit	84h	Latch off
55h	VIN_OV_FAULT_LIMIT (55h)	Sets the V_{IN} OV fault limit	R/W	Direct	0640h	16000mV
56h	VIN_OV_FAULT_RESPONSE (56h)	Configures the V _{IN} OV fault response	R/W	Bit	84h	Latch off
57h	VIN_OV_WARN_LIMIT (57h)	Sets the V _{IN} OV warning limit	R/W	Direct	0708h	18000mV
58h	VIN_UV_WARN_LIMIT (58h)	Sets the V _{IN} UV warning limit	R/W	Direct	0000h	0mV
59h	VIN_UV_FAULT_LIMIT (59h)	Sets the V _{IN} UV fault limit	R/W	Direct	0000h	0mV
5Ah	VIN_UV_FAULT_RESPONSE (5Ah)	Configures the V _{IN} UV fault response	R/W	Bit	84h	Latch off
5Bh	IIN_OC_FAULT_LIMIT (5Bh)	Sets the I _{IN} OC fault limit	R/W	Direct	1388h	50A
5Ch	IIN_OC_FAULT_RESPONSE (5Ch)	Configures the I _{IN} OC fault response	R/W	Bit	04h	Ignore
5Dh	IIN_OC_WARN_LIMIT (5Dh)	Sets the I _{IN} OC warning limit	R/W	Direct	3A98h	150A
60h	TON_DELAY (60h)	Sets turn-on delay time	R/W	Direct	0000h	0µs
61h	TON_RISE (61h)	Sets turn-on rise time	R/W	Direct	1F4h	500µs
64h	TOFF_DELAY (64h)	Sets turn-off delay time	R/W	Direct	0000h	0µs
65h	TOFF_FALL (65h)	Sets turn-off fall time	R/W	Direct	1F4h	500µs
78h	STATUS_BYTE (78h)	First byte of STATUS_WORD	Read	Bit	N/A	N/A
79h	STATUS_WORD (79h)	Summary of critical faults	Read	Bit	N/A	N/A
7Ah	<u>STATUS_VOUT (7Ah)</u>	Reports V _{OUT} warnings/faults	Read	Bit	N/A	N/A
7Bh	STATUS_IOUT (7Bh)	Reports I _{OUT} warnings/faults	Read	Bit	N/A	N/A
7Ch	<u>STATUS_INPUT (7Ch)</u>	Reports input warnings/faults	Read	Bit	N/A	N/A
7Dh	<u>STATUS_TEMPERATURE (7Dh)</u>	Reports temperature warnings/faults	Read	Bit	N/A	N/A
7Eh	<u>STATUS_CML (7Eh)</u>	Reports communication, memory, logic errors	Read	Bit	N/A	N/A
80h	STATUS_MFR_SPECIFIC (80h)	Reports other specific faults	Read	Bit	N/A	N/A
88h	READ_VIN (88h)	Reports input voltage measurement	Read	Direct	N/A	mV



Code	Command Name	Description	Туре	Data Format	Default Value	Default Setting
89h	READ_IIN (89h)	Reports input current measurement	Read	Direct	N/A	А
8Bh	READ_VOUT (8Bh)	Reports output voltage measurement	Read	Direct	N/A	mV
8Ch	READ_IOUT (8Ch)	Reports output current measurement	Read	Direct	N/A	А
8Dh	READ_TEMPERATURE_1 (8Dh)	Reports power stage temperature measurement	Read	Direct	N/A	°C
8Eh	READ_TEMPERATURE_2 (8Eh)	Reports internal temperature measurement	Read	Direct	N/A	°C
8Fh	READ_TEMPERATURE_3 (8Fh)	Reports TEMP pin temperature measurement	Read	Direct	N/A	°C
96h	READ_POUT (96h)	Reports output power	Read	Direct	N/A	W
97h	READ_PIN (97h)	Reports input power	Read	Direct	N/A	W
98h	PMBUS_REVISION (98h)	Reports the PMBus revision used	Read	Bit	33h	P1 R1.3, P2 R1.3
99h	<u>MFR_ID (99h)</u>	Stores Inventory Information	Block R/W	Bit	00000000h	Empty
9Ah	MFR_MODEL (9Ah)	Stores Inventory Information	Block R/W	Bit	00000000h	Empty
9Bh	MFR_REVISION (9Bh)	Stores Inventory Information	Block R/W	Bit	00000000h	Empty
9Dh	MFR_DATE (9Dh)	Stores Inventory Information	Block R/W	Bit	00000000h	Empty
ADh	IC_DEVICE_ID (ADh)	Reports device identification information	Block Read	Bit	ISL68225: 49D25100h ISL68236: 49D24D00h	ISL68225: 49D25100h ISL68236: 49D24D00h
AEh	IC_DEVICE_REV (AEh)	Reports device revision information	Block Read	Bit		Release revision
C5h	DMAFIX (C5h)	Fixed DMA transactions	R/W	Bit	0000h	0
C6h	DMASEQ (C6h)	Sequential DMA transaction	R/W	Bit	0000h	0
C7h	DMAADDR (C7h)	Sets the address for DMA transactions	R/W	Bit	0000h	0
CDh	PEAK_OC_LIMIT (CDh)	Sets peak per-phase OC limit	R/W	Direct	0258h	60A
CEh	PEAK_UC_LIMIT (CEh)	Sets peak per-phase UC limit	R/W	Direct	FDA8	-60A
D0h	VMON_ON (D0h)	Sets the VMON startup threshold	R/W	Direct	1C2h	4500mV
D1h	VMON_OFF (D1h)	Sets the VMON shutdown threshold	R/W	Direct	190h	4000mV
DDh	COMPPROP (DDh)	Configures proportional gain	R/W	Bit	D90907C4h	See detail
DEh	COMPINTEG (DEh)	Configures integral gain	R/W	Bit	00A9h	See detail
DFh	COMPIDFF (DFh)	Configures differential gain	R/W	Bit	000h	See detail
E0h	COMPCFB (E0h)	Configures AC current feedback	R/W	Bit	0560h	See detail
E3h	HS_BUS_CURRENT_SCALE (E3h)	Sets the high speed bus current scaling	R/W	Direct	4000h	1.0
E4h	PHASE_CURRENT (E4h)	Reports per-phase current	Read	Direct	N/A	A
E5h	PHASE_TEMPERATURE (E5h)	Reports per-phase temperature	Read	Direct	N/A	°C
E9h	PEAK_OCUC_COUNT (E9h)	Sets the count limit before fault	R/W	Bit	0606h	6 cycles for OC & UC



Code	Command Name	Description	Туре	Data Format	Default Value	Default Setting
EAh	SLOW_IOUT_OC_LIMIT (EAh)	Sets the slow I _{OUT} OC limit	R/W	Direct	C8h	20A
EBh	FAST OC FILT COUNT (EBh)	Configures the fast OC filter	R/W	Bit	0696h	Filter = 10.6µs, Delay = 100µs
ECh	SLOW_OC_FILT_COUNT (ECh)	Configures the slow OC filter	R/W	Bit	0606h	Filter = 10.6µs, Delay = 1024µs
F0h	LOOPCFG (F0h)	Defines loop operating configuration	R/W	Bit	102031F6h	See detail
F2h	RESTORE_CFG (F2h)	Identifies configuration to be restored from NVM	R/W	Bit	00h	

9.1 PMBus Use Guidelines

All commands can be read at any time.

9.2 PMBus Data Formats

9.2.1 Direct

The Direct data format is a 2-byte binary integer.

9.2.2 Linear 16 Unsigned (L16U)

The L16u data format uses a fixed exponent (hard-coded to N = -9h) and a 16-bit unsigned integer mantissa (Y) to represent the real world decimal value (X). The relation between the real world decimal value (X), N, and Y is: $X = Y \cdot 2^{-9}$.

9.2.3 Linear 16 Signed (L16S)

The L16S data format uses a fixed exponent (hard-coded to N = -9h) and a 16-bit signed integer mantissa (Y) to represent the real world decimal value (X). The relation between the real world decimal value (X), N, and Y is: $X = Y \cdot 2^{-9}$.

9.2.4 Linear 11 (L11)

The L11 data format uses a 5-bit two's complement exponent (N) and 11-bit two's complement mantissa (Y) to represent the real world decimal value (X).



onent (N)

Figure 31. Linear 11 Data Format

The relation between the real world decimal value (X), N, and Y is: $X = Y \cdot 2^N$.

9.2.5 Bit Field (Bit)

A description of Bit Field is provided in the "PMBus Command Detail" on page 40.

9.2.6 Custom (Cus)

Custom format



10. PMBus Command Detail

10.1 PAGE (00h)

Definition: Selects the communication path to Rail 0, Rail 1, both rails, or individual phases. All paged commands following this command are received and acted on by the selected destination path. Paged commands that are writeable can be written globally, but can only be read on a specific page unless otherwise specified. Global commands remain global regardless of the value of this command. Individual phase access is available by setting this command to 80h and setting the individual phase value using the PHASE command.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 00h

Command		PAGE (00h)						
Format		Bit Field						
Bit Position	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table						
Default Value	0	0 0 0 0 0 0 0 0						

Bit Value	Setting
00h	Page 0 (Rail 0)
01h	Page 1 (Rail 1)
80h	Individual phase (set by the PHASE command)
FFh	Global (All Rails)



10.2 OPERATION (01h)

Definition: Sets Enable state when configured for PMBus enable. Sets the source of the target V_{OUT} . The following table reflects the valid settings for the device.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 08h (Immediate off, Act on fault)

Command		OPERATION (01h)						
Format		Bit Field						
Bit Position	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table						
Default Value	0	0 0 0 0 1 0 0						

Bit Number	Purpose	Bit Value	Meaning
7	Enable/Disable Output	0	Disable
		1	Enable
6	Disable Behavior	0	Immediate off (decay with PWM tri-state)
		1	Soft off (Use TOFF_DELAY and TOFF_FALL)
5:4	V _{OUT} Source	00	VOUT_COMMAND
		01	VOUT_MARGIN_LOW
		10	VOUT_MARGIN_HIGH
		11	AVSBus target rail voltage
3:2	Margin Response	01	Ignore V _{OUT} OV, UV faults when margined.
		10	Act on V _{OUT} OV, UV faults when margined.
1	Not Supported	ISL68225: 0	Not supported
	AVSBus V _{OUT} Copy	ISL68236: 0	PMBus VOUT_COMMAND remains unchanged
		ISL68236 : 1	AVSBus target rail voltage setting is copied to VOUT_COMMAND on transfer back to PMBus control.
0	Not Supported	х	Not supported



10.3 ON_OFF_CONFIG (02h)

Definition: Configures the interpretation and coordination of the OPERATION command and the ENABLE pin.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 17h (ENABLE pin control, active high, immediate off)

Command		ON_OFF_CONFIG (02h)						
Format		Bit Field						
Bit Position	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table						
Default Value	0	0	0	1	0	1	1	1

Bit Number	Purpose	Bit Value	Meaning
7:5	Not Supported	000	Not supported
4:2	Sets the source of enable	0XX	Output enables any time power is present regardless of pin or OPERATION command state.
		101	Output enables from the enable pin only.
		110	Output enables from the OPERATION command only.
		111	Output enables from the enable pin AND the OPERATION command. Both must be set to enable.
1	Polarity of ENABLE pin	0	Active low
		1	Active high
0	ENABLE pin action	0	Use the configured TOFF_DELAY and TOFF_FALL settings.
	when commanding the unit to turn off	1	Turn off the output immediately (decay with PWM tri-state).

10.4 CLEAR_FAULTS (03h)

Definition: Clears all fault status bits in all registers and releases the nPMALERT pin (if asserted) simultaneously. If a fault condition still exists, the bit(s) reasserts immediately. This command does not restart a device if it is shut down, it only clears the faults.

Access: Paged

Data Length in Bytes: 0

Data Format: N/A

Type: Write only



10.5 PHASE (04h)

Definition: Sets the individual phase address for reading from PHASE_CURRENT (E4h) and PHASE_TEMPERATURE (E5h). The PAGE command must also be set to access phase information.

Access: Global

Data Length in Bytes: 1

Data Format: Direct

Type: R/W

Default Value: 00h (phase 0)

Equation: PHASE = (direct value)

Range: Phase 0 to 8

Command		PHASE (04h)						
Format		Direct						
Bit Position	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Unsigned Integer						
Default Value	0	0 0 0 0 0 0 0 0						

10.6 PAGE_PLUS_WRITE (05h)

Definition: Sets the page within a device, sends a command, and sends the data for the command in one packet.

Access: Global

Data Format: Bit Field

Type: Block Write

The PAGE_PLUS_WRITE command uses the WRITE BLOCK protocol.

Figure 32 shows an example of the PAGE_PLUS command being used to send a command that has two data bytes to be written and a PEC byte.



Figure 32. PAGE_PLUS_WRITE Command with a PEC Byte



10.7 PAGE_PLUS_READ (06h)

Definition: Sets the page within a device, sends a command, and reads the data returned by the command in one packet.

Access: Paged

Data Format: Bit Field

Type: Block Read

The PAGE_PLUS_READ command uses the BLOCK WRITE - BLOCK READ PROCESS CALL protocol.

<u>Figure 33</u> shows an example of the PAGE_PLUS command being used to send a command that has two data bytes to be read and a PEC byte.



Figure 33. PAGE_PLUS_READ Command with a PEC Byte

10.8 WRITE_PROTECT (10h)

Definition: Sets the write protection of certain configuration commands.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 00h (enable all writes)

Command		WRITE_PROTECT (10h)						
Format		Bit Field						
Bit Position	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table						
Default Value	0	0	0	0	0	0	0	0

Bits 7:0	Protection
1000 0000	Disable all writes except to WRITE_PROTECT command.
0100 0000	Disable all writes except to WRITE_PROTECT, OPERATION, and PAGE.
0010 0000	Disable all writes except to WRITE_PROTECT, OPERATION, PAGE, ON_OFF_CONFIG, and VOUT_COMMAND.
0000 0010	Disable all writes except to WRITE_PROTECT, OPERATION, PAGE, ON_OFF_CONFIG, VOUT_COMMAND, and DMA.
0000 0000	Enable all writes

Note: Any settings other than the five shown result in an invalid data fault.



10.9 CAPABILITY (19h)

Definition: Reports PMBus capabilities of the device.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Type: Read Only

Default Value (ISL68225): D0h, PEC supported, bus speed 1MHz, SMBALERT supported, Linear/Direct numeric data

Default Value (ISL68236): D4h, PEC supported, bus speed 1MHz, SMBALERT supported, Linear/Direct numeric data, AVSBus supported

Command				CAPABIL	.ITY (19h)										
Format				Bit F	Field										
Bit Position	7	6	5	4	3	2	1	0							
Access	R														
Function		R R R R R See Following Table													
Default Value for ISL68225	1	1	0	1	0	0	0	0							
Default Value for ISL68236	1	1	0	1	0	1	0	0							

Bit Number	Purpose	Bit Value	Meaning
7	PEC Support	1	PEC supported
		0	PEC not supported
6:5	Maximum Bus Speed	11	Not supported
		10	1MHz
		01	400kHz
		00	100kHz
4	SMBALERT Support	1	SMBALERT pin and response protocol is supported.
		0	SMBALERT pin and response protocol is not supported.
3	Numeric Format	1	Numeric data, IEEE half precision floating point format
		0	Numeric data, Linear/Direct
2	AVSBus Support	1	ISL68236: AVSBus supported
		0	ISL68225: AVSBus not supported
1:0	Not Supported	00	Not supported



10.10 SMBALERT_MASK (1Bh)

Definition: Prevents a warning or fault condition from asserting the SMBALERT# signal. Can be used on the following PMBus status commands: STATUS_VOUT, STATUS_IOUT, STATUS_INPUT, STATUS_TEMPERATURE, STATUS_CML, and STATUS_MFR_SPECIFIC.

Access: Paged

Data Format: Bit Field

Type: Block R/W

Default: 00h

<u>Figures 34</u> and <u>35</u> show the command format used to block a status bit or bits from causing the SMBALERT# signal to be asserted. The bits in the mask byte align with the bits in the corresponding status register. For example, if the STATUS_TEMPERATURE command code is sent with the mask byte 01000000b, an over-temperature warning condition would be blocked from asserting SMBALERT#.

Note: <u>Figure 34</u> shows the command format used by the host to determine the SMBALERT_MASK setting for a given status register.



Figure 34. SMBALERT_MASK Command Packet Format



Figure 35. Retrieving the SMBALERT_MASK Setting for a Given Status Register

10.11 VOUT_MODE (20h)

Definition: Returns the supported V_{OUT} mode. Direct mode, 1mV per LSB.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Type: Read Only

Default Value: 40h

Command				VOUT_MO	ODE (20h)										
Format				Bit F	ield										
Bit Position	7	7 6 5 4 3 2 1 0													
Access	R	R	R	R	R	R	R	R							
Function		Mode				Exponent									
Default Value	0	1	0	0	0	0	0	0							



10.12 VOUT_COMMAND (21h)

Definition: Sets the value of V_{OUT} when the OPERATION command is configured for PMBus nominal operation. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0384h (900mV)

Units: mV

Equation: V_{OUT} Command = (Direct value)

Range: 0mV to 3050mV

Command							VOUT	г_сом	MAND	(21h)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0 / DAM DAM														0
Access	R/W															R/W
Function							U	nsigne	d Intege	er						
Default Value	0	0	0	0	0	0	1	1	1	0	0	0	0	1	0	0

10.13 VOUT_TRIM (22h)

Definition: Applies a fixed trim voltage to the output voltage command value. This command is typically used to calibrate a device in the application circuit. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0000h

Units: mV

Equation: V_{OUT} Trim = (Direct value)

Range: Any value that results in the V_{OUT} target being between 0V and VOUT_MAX

Command							V	Ουτ_τι	RIM (22	:h)						
Format								Dir	ect							
Bit Position	15															0
Access	R/W															R/W
Function							Two's	Comple	ement I	nteger						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0



10.14 VOUT_CAL_OFFSET (23h)

Definition: Applies a fixed offset voltage to the output voltage command value. This command is typically used to calibrate a device in the application circuit. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0000h

Units: mV

Equation: V_{OUT} Cal Offset = (Direct value)

Range: Any value that results in the V_{OUT} target being between 0V and VOUT_MAX

Command							VOUT_	CAL_0	OFFSE	T (23h)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														0
Access	R/W															R/W
Function							Two's	Comple	ement I	nteger						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

10.15 VOUT_MAX (24h)

Definition: Sets the absolute maximum V_{OUT} regulation value regardless of any other commands or combinations.1mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0BEAh (3050mV)

Units: mV

Equation: V_{OUT} Max = (Direct value)

Range: 0mV to 3050mV

Command							V	оит_м	AX (24	h)						
Format								Dir	ect							
Bit Position	15															0
Access	R/W															R/W
Function							L	Insigne	d Intege	er						
Default Value	0	0	0	0	1	0	1	1	1	1	1	0	1	0	1	0



10.16 VOUT_MARGIN_HIGH (25h)

Definition: Sets the value of V_{OUT} when the OPERATION command is configured for margin high. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2 Data Format: Direct Type: R/W Default Value: 03B1h (945mV) Units: mV

Equation: V_{OUT} Margin High = (Direct value)

Range: 0mV to 3050mV

Command						,	VOUT_	MARG	IN_HIG	H (25h))					
Format								Dir	ect							
Bit Position	15															
Access	R/W															
Function							U	nsigne	d Intege	er						
Default Value	0	0	0	0	0	0	1	1	1	0	1	1	0	0	0	1

10.17 VOUT_MARGIN_LOW (26h)

Definition: Sets the value of V_{OUT} when the OPERATION command is configured for margin low. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0357h (855mV)

Units: mV

Equation: V_{OUT} Margin Low = (Direct value)

Range: 0mV to 3050mV

Command							VOUT_	MARG	IN_LO\	V (26 h)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														0
Access	R/W															R/W
Function							U	Insigne	d Intege	er						
Default Value	0	0	0	0	0	0	1	1	0	1	0	1	0	0	0	1



10.18 VOUT_TRANSITION_RATE (27h)

Definition: Defines the output voltage rate of change during regulation. 0.01mV/µs per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 09C4h (25mV/µs)

Units: mV/µs

Equation: V_{OUT} Transition Rate = (Direct value) / 100

Range: 10µV/µs to 100mV/µs

Command						VC	UT_TF	RANSIT	ION_R	ATE (2	7h)					
Format								Dir	ect							
Bit Position	15															
Access	R/W															
Function							U	nsigne	d Intege	er						
Default Value	0	0	0	0	1	0	0	1	1	1	0	0	0	1	0	0

10.19 VOUT_DROOP (28h)

Definition: Sets the rate at which output voltage changes relative to output current during regulation. 10μ V/A per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0000h (0µV/A)

Units: µV/A

Equation: V_{OUT} Droop = (Direct value) x 10

Range: 0µV/A to 16000µV/A

Command							VO	UT_DR	00P (2	8h)						
Format								Dir	ect							
Bit Position	15															0
Access	R/W															R/W
Function							U	nsigne	d Intege	er						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0



10.20 VOUT_MIN (2Bh)

Definition: Sets the absolute minimum voltage that is delivered to the output during regulation. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2 Data Format: Direct Type: R/W Default Value: 0000h Units: mV Equation: V_{OUT} Min = (Direct value)

Range: 0mV to 3050mV

Command							V	OUT_N	IIN (2B	h)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0 4 5 5 4 3 2 1 0 5 4 3 2 1 0														0
Access	R/W	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0 R/W R/W														
Function							U	Insigne	d Intege	er						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

10.21 FREQUENCY_SWITCH (33h)

Definition: Sets the PWM switching frequency during regulation. 1kHz per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0258h (600kHz)

Units: kHz

Equation: Frequency Switch = (Direct value)

Range: 200kHz to 2MHz

Command						F	REQU	ENCY_	SWITC	:H (33h)					
Format								Dir	ect							
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function							U	nsigne	d Intege	er						
Default Value	0	0 0 0 0 0 0 1 0 1 1 0 0 0														



10.22 POWER_MODE (34h)

Definition: Sets the power conversion mode.

Maximum Efficiency Mode (0) defaults:

- Voltage down transitions happen immediately with decay (PWM tri-state).
- Phase dropping is enabled irrespective of the APD setting in the LOOPCFG command.
- Diode emulation can be enabled using LOOPCFG[6].

Maximum Power Mode (3) defaults:

- Voltage down transitions happen as programmed in the TOFF_DELAY and TOFF_FALL commands.
- Phase automatic add/drop is enabled using LOOPCFG[0].
- Diode emulation can be enabled using LOOPCFG[28].

MFR Defined (4) defaults:

- Voltage down transitions happen immediately with decay (PWM tri-state).
- Phase dropping is enabled irrespective of the APD setting in the LOOPCFG command.
- Diode emulation can be enabled using LOOPCFG[6] and LOOPCFG[28].

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 03h, Maximum Power

Command				POWER_M	IODE (34h)								
Format				Bit F	ield								
Bit Position	7	7 6 5 4 3 2 1 0											
Access	R/W R/W R/W R/W R/W R/W R/W												
Function				See Follow	wing Table								
Default Value	0	0 0 0 0 0 0 1 1											

Bit Value	Setting
04h	MFR defined
03h	Maximum power
00h	Maximum efficiency



10.23 VIN_ON (35h)

Definition: Sets the input voltage rising threshold at which the output can be enabled. 10mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 02BCh (7000mV)

Units: mV

Equation: V_{IN} On = (Direct value) x 10

Range: -327680mV to 327670mV

Command								VIN_O	N (35h)						
Format								Dir	ect						
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0												0	
Access	R/W	R/W											R/W		
Function		Two's Complement Integer													
Default Value	0	0 0 0 0 0 0 1 0 1 0 1 1 1 1 0 0													

10.24 VIN_OFF (36h)

Definition: Sets the input voltage falling threshold at which the output disables. 10mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 01F4 (5000mV)

Units: mV

Equation: V_{IN} Off = (Direct value) x 10

Range: -327680mV to 327670mV

Command							,	VIN_OF	F (36h)					
Format								Dir	ect						
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0													
Access	R/W	R/W													
Function		Two's Complement Integer													
Default Value	0	0 0 0 0 0 0 0 1 1 1 1 1 0 1 0 0													



10.25 VOUT_OV_FAULT_LIMIT (40h)

Definition: Sets the disabled rail overvoltage threshold. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0C1Ch (3100mV)

Units: mV

Equation: V_{OUT} OV Fault Limit = (Direct value)

Range: 0mV to 3050mV

Command						v	ουτ_ο	V_FAL	ILT_LIN	/IT (40	h)					
Format								Dir	ect							
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W												R/W		
Function		Unsigned Integer														
Default Value	0	0 0 0 0 1 1 0 0 0 0 1 1 0 0														



10.26 VOUT_OV_FAULT_RESPONSE (41h)

Definition: Configures the output overvoltage fault response. For a fault to be considered cleared, the output must drop by 100mV.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 84h (latch off)

Command			VOU	T_OV_FAULT	RESPONSE	(41h)								
Format				Bit F	ield									
Bit Position	7	7 6 5 4 3 2 1 0												
Access	R/W R/W R/W R/W R/W R/W R/W													
Function				See Follow	wing Table									
Default Value	1	1 0 0 0 0 1 0 0												

Bit	Field Name	Value	Description				
7:6	Response Behavior	00	Continue without interruption.				
	During a fault, the device:	01	Not supported				
	Pulls PMALRT low	10	Disable and retry according to the setting in Bits [5:3].				
	• Sets the related fault bit in the status registers.	11	Not supported				
5:3	Retry Setting	000	No retry. The output remains disabled until the rail is restarted.				
		001-110	Not supported				
		111	Attempts to restart continuously, without limitation, until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].				
2:0	Delay Time before	before 000 0ms delay (not recommended)					
	Retry	001-110	Delay 25ms per LSB				
		111 Delay 175ms					



10.27 VOUT_UV_FAULT_LIMIT (44h)

Definition: Sets the output undervoltage fault threshold. 1mV per LSB. This fault is masked during ramp or when disabled.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0V

Units: mV

Equation: V_{OUT} UV Fault Limit = (Direct value)

Range: 0V to 3.05V

Command						١	/Ουτ_ι	JV_FAU	ILT_LIN	IIT (44 h	ı)					
Format								Dir	ect							
Bit Position	15	5 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	/W R/W R/W R/W R/W R/W R/W R/W R/W R/W R														
Function							ι	Jnsigne	d Intege	er						
Default Value	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0														



10.28 VOUT_UV_FAULT_RESPONSE (45h)

Definition: Configures the output undervoltage fault response. This fault is masked during ramp or when disabled.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 84h (latch off)

Command			VOU	T_UV_FAULT	RESPONSE	(45h)								
Format				Bit F	ield									
Bit Position	7	7 6 5 4 3 2 1 0												
Access	R/W R/W R/W R/W R/W R/W R/W													
Function				See Follo	wing Table									
Default Value	1	1 0 0 0 0 1 0 0												

Bit	Field Name	Value	Description
7:6	Response Behavior	00	Continue without interruption.
	During a fault, the device:	01	Not supported
	Pulls PMALRT low	10	Disable and retry according to the setting in Bits [5:3].
	• Sets the related fault bit in the status registers.	11	Not supported
5:3	Retry Setting	000	No retry. The output remains disabled until the rail is restarted.
		001-110	Not supported
		111	Attempts to restart continuously, without limitation, until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].
2:0	Delay Time before	000	Delay 0ms (not recommended)
	Retry	001-110	Delay 25ms per LSB
		111	Delay 175ms



10.29 IOUT_OC_FAULT_LIMIT (46h)

Definition: Sets the fast sum output overcurrent fault threshold. 0.1A per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 12Ch (30A)

Units: A

Equation: I_{OUT} OC Fault Limit = (Direct value) / 10

Range: 0A to 3276.7A

Command						IC	ο_τυς	C_FAU	LT_LIN	IIT (46h	ו)					
Format								Dir	ect							
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0													0	
Access	R/W	R/W												R/W		
Function							U	nsigne	d Intege	er						
Default Value	0	0 0 0 0 0 0 0 0 1 0 1 0 1 0 0														



10.30 IOUT_OC_FAULT_RESPONSE (47h)

Definition: Configures the output overcurrent fault response for all I_{OUT} OC detection methods. This response setting is also applied to output undercurrent faults.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: C4h (latch off)

Command		IOUT_OC_FAULT_RESPONSE (47h)							
Format				Bit F	ield				
Bit Position	7	6	5	4	3	2	1	0	
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Function				See Follow	wing Table				
Default Value	1	1 1 0 0 0 1 0 0							

Bit	Field Name	Value	Description
7:6	ResponseBehavior	00	Continue without interruption.
	During a fault, the device:	01-10	Not supported
	Pulls PMALRT low	11	Disable and retry as set in Bits [5:3]
	• Sets the related fault bit in the status registers.		
5:3	Retry Setting	000	No retry. The output remains disabled until the rail is restarted.
		001-110	Not supported
		111	Attempts to restart continuously, without limitation, until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].
2:0	Delay Time before Retry	000	Delay 0ms (not recommended)
		001-110	Delay 25ms per LSB
		111	Delay 175ms



10.31 OT_FAULT_LIMIT (4Fh)

Definition: Sets the power stage over-temperature fault limit. 1°C per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 007Dh (125°C)

Units: °C

Equation: OT Fault Limit = (Direct value)

Range: 0°C to +150°C

Command		OT_FAULT_LIMIT (4Fh)														
Format		Direct														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Unsigned Integer														
Default Value	0	0	0	0	0	0	0	0	0	1	1	1	1	1	0	1



10.32 OT_FAULT_RESPONSE (50h)

Definition: Configures the power stage over-temperature fault response. For a fault to be considered cleared, the temperature must drop 5°C below the OT fault threshold value.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 84h (latch off)

Command		OT_FAULT_RESPONSE (50h)							
Format		Bit Field							
Bit Position	7	6	5	4	3	2	1	0	
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Function				See Follo	wing Table				
Default Value	1	0 0 0 0 1 0 0							

Bit	Field Name	Value	Description
7:6	Response Behavior	00	Continue without interruption.
	During a fault, the device:	01	Not supported
	Pulls PMALRT low	10	Disable and retry according to the setting in Bits [5:3].
	 Sets the related fault bit in the status registers. 	11	Not supported
5:3	Retry Setting	000	No retry. The output remains disabled until the rail is restarted.
		001-110	Not supported
	-	111	Attempts to restart continuously, without limitation, until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].
2:0	Delay Time before Retry	000	Delay 0ms (not recommended)
		001-110	Delay 25ms per LSB
		111	Delay 175ms



10.33 OT_WARN_LIMIT (51h)

Definition: Sets the power stage over-temperature warning limit. 1°C per LSB.

Access: Paged

Data Length in Bytes: 2 Data Format: Direct Type: R/W Default Value: 006Eh (110°C) Units: °C

Equation: OT Warn Limit = (Direct value)

Range: 0°C to 150°C

Command		OT_WARN_LIMIT (51h)														
Format		Direct														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Two's Complement Integer														
Default Value	0	0	0	0	0	0	0	0	0	1	1	0	1	1	1	0

10.34 UT_FAULT_LIMIT (53h)

Definition: Sets the power stage under-temperature fault limit. 1°C per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: FFD8h (-40°C)

Units: °C

Equation: UT Fault Limit = (Direct value)

Range: -50°C to 150°C

Command		UT_FAULT_LIMIT (53h)														
Format		Direct														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Two's Complement Integer														
Default Value	1	1	1	1	1	1	1	1	1	1	0	1	1	0	0	0



10.35 UT_FAULT_RESPONSE (54h)

Definition: Configures the power stage under-temperature fault response. For the fault to be considered cleared, the temperature must rise 5°C above the UT fault threshold value.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 84h (latch off)

Command		UT_FAULT_RESPONSE (54h)							
Format		Bit Field							
Bit Position	7	6	5	4	3	2	1	0	
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Function				See Follo	wing Table				
Default Value	1	1 0 0 0 0 1 0 0							

Bit	Field Name	Value	Description
7:6	Response Behavior	00	Continue without interruption.
	During a fault, the device:	01	Not supported
	Pulls PMALRT low	10	Disable and retry according to the setting in Bits [5:3].
	• Sets the related fault bit in the status registers.	11	Not supported
5:3	Retry Setting	000	No retry. The output remains disabled until the device is restarted.
		001-110	Not supported
		111	Attempts to restart continuously without limitation until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].
2:0	Delay Time before	000	Delay 0ms (not recommended)
	Retry	001-110	Delay 25ms per LSB
		111	Delay 175ms



10.36 VIN_OV_FAULT_LIMIT (55h)

Definition: Sets the V_{IN} overvoltage fault threshold. 10mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0640h (16000mV)

Units: mV

Equation: V_{IN} OV Fault Limit = (Direct value) x 10

Range: -327680mV to 327670mV

Command		VIN_OV_FAULT_LIMIT (55h)														
Format		Direct														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Two's Complement Integer														
Default Value	0	0	0	0	0	1	1	0	0	1	0	0	0	0	0	0



10.37 VIN_OV_FAULT_RESPONSE (56h)

Definition: Configures the input overvoltage fault response. For a fault to be considered cleared, the input voltage must drop by 1/16th of the OV fault threshold value.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 84h (latch off)

Command		VIN_OV_FAULT_RESPONSE (56h)							
Format		Bit Field							
Bit Position	7	6	5	4	3	2	1	0	
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Function				See Follo	wing Table				
Default Value	1	1 0 0 0 0 1 0 0							

Bit	Field Name	Value	Description
7:6	Response Behavior	00	Continue without interruption.
	During a fault, the device:	01	Not supported
	Pulls PMALRT low	10	Disable and retry according to the setting in Bits [5:3].
	• Sets the related fault bit in the status registers.	11	Not supported
5:3	Retry Setting	000	No retry. The output remains disabled until the device is restarted.
		001-110	Not supported
		111	Attempts to restart continuously without limitation until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].
2:0	Delay Time before	000	Delay 0ms (not recommended)
	Retry	001-110	Delay 25ms per LSB
		111	Delay 175ms



10.38 VIN_OV_WARN_LIMIT (57h)

Definition: Sets the V_{IN} undervoltage fault threshold. 10mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0708h (18000mV)

Units: mV

Equation: V_{IN} OV Warn Limit = (Direct value) x 10

Range: 0mV to 327670mV

Command						,	VIN_O\	/_WAR	N_LIM	IT (57h))					
Format								Dir	ect							
Bit Position	15															
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function							Two's	Comple	ement I	nteger						
Default Value	0	0 0 0 1 1 1 0 0 0 1 0														

10.39 VIN_UV_WARN_LIMIT (58h)

Definition: Sets the V_{IN} undervoltage warning threshold. 10mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0000h (0mV)

Units: mV

Equation: V_{IN} UV Warn Limit = (Direct value) x 10

Range: 0mV to 327670mV

Command						,	VIN_U\	/_WAR	N_LIMI	T (58h))					
Format								Dir	ect							
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W						
Function				•	•		Two's	Comple	ement I	nteger		•		•	•	•
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0



10.40 VIN_UV_FAULT_LIMIT (59h)

Definition: Sets the V_{IN} undervoltage fault threshold. 10mV per LSB. If using VIN_ON and VIN_OFF commands, this command should be set to 0V.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0000h (0mV)

Units: mV

Equation: V_{IN} UV Fault Limit = (Direct value) x 10

Range: -327680mV to 327670mV

Command						,	VIN_U\	/_FAUL	T_LIM	IT (59h)					
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function							Two's	Comple	ement I	nteger						
Default Value	0	Two's Complement Integer 0														



10.41 VIN_UV_FAULT_RESPONSE (5Ah)

Definition: Configures the input undervoltage fault response. For a fault to be considered cleared, the input voltage must rise by 1/16th of the UV fault threshold value.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 84h (latch off)

Command			VIN	_UV_FAULT_I	RESPONSE (5	5Ah)						
Format				Bit F	Field							
Bit Position	7 6 5 4 3 2 1 0											
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W				
Function				See Follo	wing Table							
Default Value	1	0	0	0	0	1	0	0				

Bit	Field Name	Value	Description
7:6	Response Behavior	00	Continue without interruption.
	During a fault, the device:	01	Not supported
	Pulls PMALRT low	10	Disable and retry according to the setting in Bits [5:3].
	• Sets the related fault bit in the status registers.	11	Not supported
5:3	Retry Setting	000	No retry. The output remains disabled until the device is restarted.
		001-110	Not supported
		111	Attempts to restart continuously, without limitation, until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].
2:0	Delay Time before	000	Delay 0ms (not recommended)
	Retry	001-110	Delay 25ms per LSB
		111	Delay 175ms



10.42 IIN_OC_FAULT_LIMIT (5Bh)

Definition: Sets the input overcurrent fault threshold for the synthesized input current reading at READ_IIN. 10mA per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 1388h (50A)

Units: A

Equation: I_{IN} OC Fault Limit = (Direct value) / 100

Range: -327.68A to 327.67A

Command							IIN_OC	_FAUL	T_LIMI	T (5Bh))					
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function							Two's	Comple	ement I	nteger						
Default Value	0	0 0 1 0 0 1 1 1 0 0 0 1 0 0 0														



10.43 IIN_OC_FAULT_RESPONSE (5Ch)

Definition: Configures the input overcurrent fault response for the synthesized input current reading at READ_IIN.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 04h (ignore)

Command			lin_	_OC_FAULT_F	RESPONSE (5	Ch)						
Format				Bit F	Field							
Bit Position	7 6 5 4 3 2 1 0											
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W				
Function				See Follo	wing Table							
Default Value	0	0	0	0	0	1	0	0				

Bit	Field Name	Value	Description
7:6	Response Behavior	00	Continue without interruption.
	During a fault, the device:	01-10	Not supported
	 Pulls PMALRT low Sets the related fault bit in the status registers. 	11	Disable and retry as set in Bits [5:3].
5:3	Retry Setting	000	No retry. The output remains disabled until the device is restarted.
		001-110	Not supported
		111	Attempts to restart continuously, without limitation, until it is commanded OFF (by the CONTROL pin or OPERATION command), bias power is removed, or another fault condition causes the unit to shut down. The time between retries is set by Bits [2:0].
2:0	Delay Time before	000	Delay 0ms (not recommended)
	Retry	001-110	Delay 25ms per LSB
		111	Delay 175ms



10.44 IIN_OC_WARN_LIMIT (5Dh)

Definition: Sets the input overcurrent warning threshold. 10mA per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 3A98h (150A)

Units: A

Equation: I_{IN} OC Warn Limit = (Direct value) / 100

Command							IIN_OC	_WAR	N_LIMI	T (5Dh))					
Format								Dir	ect							
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W						
Function							Two's	Comple	ement I	nteger						
Default Value	0	0	1	1	1	0	1	0	1	0	0	1	1	0	0	0

10.45 TON_DELAY (60h)

Definition: Sets the delay time from when the device is enabled to the start of V_{OUT} rise. 10µs per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0000h (0µs)

Units: µs

Equation: t_{ON} Delay = (Direct value) x 10

Range: 0µs to 655534µs

Command							тс	DN_DE	LAY (60)h)						
Format								Dir	ect							
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W							
Function							U	Insigne	d Intege	er						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0



10.46 TON_RISE (61h)

Definition: Sets the rise time of V_{OUT} during enable. 1µs per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 1F4h (500µs)

Units: µs

Equation: t_{ON} Rise = (Direct value)

Range: 0µs to 10000µs

Command							т	ON_RI	SE (611	ר)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function							U	nsigne	d Intege	er						
Default Value	0	0 0 0 0 0 1 0 1 1 1 1 1														

10.47 TOFF_DELAY (64h)

Definition: Sets the delay time of V_{OUT} during disable when configured for soft off. 10µs per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 0000h (0µs)

Units: µs

Equation: t_{OFF} Delay = (Direct value) x 10

Range: 0µs to 655534µs

Command							то	FF_DE	LAY (6	4h)						
Format								Dir	ect							
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W							
Function							U	Insigne	d Intege	er						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0


10.48 TOFF_FALL (65h)

Definition: Sets the fall time of V_{OUT} during disable when configured for soft off. 1µs per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 1F4h (500µs)

Units: µs

Equation: t_{OFF} Fall = (Direct value)

Range: 0µs to 10000µs

Command		TOFF_FALL (65h)														
Format		Direct														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Unsigned Integer														
Default Value	0	0	0	0	0	0	0	1	0	1	0	0	1	1	1	1



10.49 STATUS_BYTE (78h)

Definition: Returns a summary of the device status. Based on the information in this byte, the host can get more information by reading the appropriate status registers. Depending on the setting of the PAGE command, this command returns information about individual rails or a global summary of all rail statuses.

Access: Paged and Global

Data Length in Bytes: 2

Data Format: Bit Field

Command		STATUS_BYTE (78h)							
Format		Bit Field							
Bit Position	7	7 6 5 4 3 2 1 0							
Access	R	R	R	R	R	R	R	R	
Function				See Follow	wing Table				

Bit Number	Status Bit Name	Meaning
7	BUSY	A fault was declared because the device was busy and unable to respond.
6	OFF	This bit is asserted if the unit is not providing power to the output, regardless of the reason, including simply not being enabled.
5	VOUT_OV_FAULT	An output overvoltage fault occurred.
4	IOUT_OC_FAULT	An output overcurrent fault occurred.
3	VIN_UV_FAULT	An input undervoltage fault occurred.
2	TEMPERATURE	A temperature fault or warning occurred.
1	CML	A communications, memory, or logic fault occurred.
0	None of the Above	A fault other than those listed above occurred.



10.50 STATUS_WORD (79h)

Definition: Returns a summary of the device status. Based on the information in these bytes, the host can get more information by reading the appropriate status registers. Depending on the setting of the PAGE command, this command returns information about individual rails or a global summary of all rail statuses. The low byte of the STATUS_WORD is the same as the STATUS_BYTE (78h) command.

Access: Paged and Global

Data Length in Bytes: 2

Data Format: Bit Field

Type: Read Only

Command		STATUS_WORD (79h)														
Format		Bit Field														
Bit Position	15	i 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function							Se	e Follov	wing Ta	ble						

Bit Number	Status Bit Name	Meaning
15	V _{OUT}	An output voltage fault or warning occurred.
14	I _{OUT}	An output current fault occurred.
13	INPUT	An input voltage fault or warning occurred.
12	MFR_SPECIFIC	A manufacturer specific fault or warning occurred.
11	POWER_GOOD #	The POWER_GOOD signal is negated (<u>Note 8</u>).
10:9	Not Supported	Not supported
8	Unknown	A fault other than those described in Bits[15:9] occurred.
7	Busy	Device busy and unable to respond.
6	OFF	This bit is asserted if the unit is not providing power to the output, regardless of the reason, including simply not being enabled.
5	VOUT_OV_FAULT	An output overvoltage fault occurred.
4	IOUT_OC_FAULT	An output overcurrent fault occurred.
3	VIN_UV_FAULT	An input undervoltage fault occurred.
2	TEMPERATURE	A temperature fault or warning occurred.
1	CML	A communications, memory, or logic fault occurred.
0	None of the Above	A status change other than those listed above occurred.

Note:

8. If the POWER_GOOD# Bit is set, this indicates that the POWER_GOOD signal is signaling that the output power is not good.



10.51 STATUS_VOUT (7Ah)

Definition: Returns a summary of output voltage status.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: Read Only

Command		STATUS_VOUT (7Ah)							
Format		Bit Field							
Bit Position	7	7 6 5 4 3 2 1 0							
Access	R	R	R	R	R	R	R	R	
Function				See Follo	wing Table				

Bit Number	Status Bit Name	Meaning
7	VOUT_OV_FAULT	Indicates an output overvoltage fault occurred.
6:5	Not Supported	Not supported
4	VOUT_UV_FAULT	Indicates an output undervoltage fault occurred.
3	VOUT_MAX Warning	Indicates an output voltage maximum warning occurred.
2:0	Not Supported	Not supported

10.52 STATUS_IOUT (7Bh)

Definition: Returns a summary of output current status.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Command		STATUS_IOUT (7Bh)							
Format		Bit Field							
Bit Position	7	7 6 5 4 3 2 1 0							
Access	R	R	R	R	R	R	R	R	
Function				See Follo	wing Table				

Bit Number	Status Bit Name	Meaning
7	IOUT_OC_FAULT	An output overcurrent fault occurred.
6	Not Supported	Not supported
5	Not supported	Not supported
4	IOUT_UC_FAULT	An output undercurrent fault occurred.
3	Current Share Fault	A current share fault occurred.
2:0	Not Supported	Not supported



10.53 STATUS_INPUT (7Ch)

Definition: Returns a summary of input status.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: Read Only

Command		STATUS_INPUT (7Ch)								
Format		Bit Field								
Bit Position	7	7 6 5 4 3 2 1 0								
Access	R	R	R	R	R	R	R	R		
Function				See Follo	wing Table					

Bit Number	Status Bit Name	Meaning
7	VIN_OV_FAULT	An input overvoltage fault occurred.
6	VIN_OV_WARN	An input overvoltage warning occurred.
5	VIN_UV_WARN	An input undervoltage warning occurred.
4	VIN_UV_FAULT	An input undervoltage fault occurred.
3	VIN_ON/OFF	Disabled due to insufficient input voltage. This could be VIN or VMON.
2	IIN_OC_FAULT	An input overcurrent fault occurred.
1	IIN_OC_WARN	An input overcurrent warning occurred.
0	Not Supported	Not supported

10.54 STATUS_TEMPERATURE (7Dh)

Definition: Returns a summary of temperature status.

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Command		STATUS_TEMPERATURE (7Dh)								
Format		Bit Field								
Bit Position	7	7 6 5 4 3 2 1 0								
Access	R	R	R	R	R	R	R	R		
Function				See Follo	wing Table					

Bit Number	Status Bit Name	Meaning
7	OT_FAULT	An over-temperature fault occurred.
6	OT_WARN	An over-temperature warning occurred.
5	Not Supported	Not supported
4	UT_FAULT	An under-temperature fault occurred.
3:0	Not Supported	Not supported



10.55 STATUS_CML (7Eh)

Definition: Returns a summary of any communications, logic, and/or memory errors.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Command				STATUS_	CML (7Eh)										
Format				Bit F	Field										
Bit Position	7	7 6 5 4 3 2 1 0													
Access	R	R	R	R	R	R	R	R							
Function	See Following Table														

Bit Number	Status Bit Name	Meaning
7	IUCR	Invalid or unsupported PMBus command was received. This bit sets during device discovery when using PowerNavigator.
6	IUDR	The PMBus command was sent with invalid or unsupported data.
5	PECF	A packet error check failure was detected in the PMBus command.
4	MFD	Memory fault detected. This bit sets if the selected NVM configuration location is empty or invalid.
3	PFD	Processor fault detected.
2	Not Supported	Not supported
1	OCF	A communication fault other than the ones listed in this table occurred.
0	OMLF	A memory or logical fault not listed previously was detected.



10.56 STATUS_MFR_SPECIFIC (80h)

Definition: Returns a summary of the manufacturer specific status.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Type: Read Only

Command			S	TATUS_MFR_	SPECIFIC (80	h)									
Format				Bit F	ield										
Bit Position	7	7 6 5 4 3 2 1 0													
Access	R	R	R	R	R	R	R	R							
Function	See Following Table														

Bit	Status Bit Name	Meaning
7	ADCUNLOCK	ADC clock unlock detected.
6	Not Supported	Not supported
5	CFP Fault	A CFP fault occurred.
4	Internal Temperature Fault	The controller internal temperature exceeded 130 °C.
3	BBEVENT	A Black Box event occurred.
2	LMSEvent	A Last Man Standing event occurred.
1	SPSFault	An SPS overcurrent and/or over-temperature event occurred.
0	Not Supported	Not supported

10.57 READ_VIN (88h)

Definition: Returns the input voltage reading. Scaled as10mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: mV

Equation: Read V_{IN} = (Direct value) x 10

Command							R	EAD_V	/IN (88I	ר)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														



10.58 READ_IIN (89h)

Definition: Returns the synthesized input current reading. 10mA per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: A

Equation: Read I_{IN} = (Direct value) / 100

Command							F	READ_I	IN (89h	I)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														

10.59 READ_VOUT (8Bh)

Definition: Returns the output voltage reading. 1mV per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: mV

Equation: Read V_{OUT} = (Direct value)

Command							RE	AD_VC	OUT (8E	3h)						
Format		Direct														
Bit Position	15	5 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Unsigned Integer														



10.60 READ_IOUT (8Ch)

Definition: Returns the output current reading. 0.1A per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: A

Equation: Read I_{OUT} = (Direct value) / 10

Command							RE	AD_IO	OUT (80	:h)						
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														

10.61 READ_TEMPERATURE_1 (8Dh)

Definition: Returns the temperature reading of the hottest power stage per configured rail. 1°C per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: °C

Equation: Read Temperature 1 = (Direct value)

Command						R	AD_T	EMPER	ATURE	E_1 (8D)h)					
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														



10.62 READ_TEMPERATURE_2 (8Eh)

Definition: Returns the internal controller temperature reading. 1°C per LSB.

Access: Global

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: °C

Equation: Read Temperature 2 = (Direct value)

Command						R	EAD_T	EMPER	ATUR	E_2 (8E	ih)					
Format								Dir	ect							
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														

10.63 READ_TEMPERATURE_3 (8Fh)

Definition: Returns the temperature reading from the TEMP pins. 1°C per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: °C

Equation: Read Temperature 3 = (Direct value)

Command						R	EAD_TI	EMPER	ATURE	E_3 (8F	'n)					
Format								Dir	ect							
Bit Position	15	5 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														



10.64 READ_POUT (96h)

Definition: Returns the output power. 1W per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: W

Equation: Read P_{OUT} = (Direct value)

Command							RE	AD_PO	OUT (90	6h)						
Format		Direct														
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														

10.65 READ_PIN (97h)

Definition: Returns the input power. 1W per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: W

Equation: READ_PIN = (Direct value)

Command							R	EAD_F	PIN (971	h)						
Format		Direct														
Bit Position	15	5 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														



10.66 PMBUS_REVISION (98h)

Definition: Returns the revision of the PMBus specification to which the device is compliant.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Type: Read Only

Default Value: 33h (Part 1 Revision 1.3, Part 2 Revision 1.3)

Command				PMBUS_RE	VISION (98h)										
Format				Bit F	Field										
Bit Position	7	7 6 5 4 3 2 1 0													
Access	R	R R R R R R R													
Function				See Follo	wing Table										
Default Value	0 0 1 1 0 0 1 1														

Bits 7:4	Part 1 Revision	Bits 3:0	Part 2 Revision
0000	1.0	0000	1.0
0001	1.1	0001	1.1
0010	1.2	0010	1.2
0011	1.3	0011	1.3

10.67 MFR_ID (99h)

Definition: Stores inventory information during manufacturing of end products. 4 bytes of space with no defined format.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: Block R/W

Default Value: 0000000h (empty)

10.68 MFR_MODEL (9Ah)

Definition: Stores inventory information during manufacturing of end products. 4 bytes of space with no defined format.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: Block R/W

Default Value: 0000000h (empty)



10.69 MFR_REVISION (9Bh)

Definition: Stores inventory information during manufacturing of end products. 4 bytes of space with no defined format.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: Block R/W

Default Value: 0000000h (empty)

10.70 MFR_DATE (9Dh)

Definition: Stores inventory information during manufacturing of end products. 4 bytes of space with no defined format.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: Block R/W

Default Value: 0000000h (empty)

10.71 IC_DEVICE_ID (ADh)

Definition: Reports device identification information.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: Block Read

Default Value: ISL68225: 49D25100h, ISL68236: 49D24D00h

Command		IC_DEVICE_ID (A	Dh) for ISL68225												
Format		Bit Field													
Byte Position	3 2 1 0														
Function	MFR Code	ID High Byte	ID Low Byte	Reserved											
Default Value	49h D2h 51h 00h														

Command		IC_DEVICE_ID (A	Dh) for ISL68236												
Format		Bit Field													
Byte Position	3	3 2 1 0													
Function	MFR Code	ID High Byte	ID Low Byte	Reserved											
Default Value	49h	49h D2h 4Dh 00h													



10.72 IC_DEVICE_REV (AEh)

Definition: Reports device revision information.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: Block Read

Default Value: Based on the revision released

Command		IC_DEVICE_REV (AEh)	
Format		Bit Field	
Bit Position	31:24	23:8	7:0
Function	Hardware Revision	Reserved	Firmware Revision

10.73 DMAFIX (C5h)

Definition: Location for DMA access when performing a fixed address memory access. There is no physical storage for this register.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: R/W

Default Value: 0000h

Units: N/A

10.74 DMASEQ (C6h)

Definition: Location for DMA access when performing a auto-increment address memory access. A series of reads or writes accesses sequential memory locations, with the value of DMAADDR incremented with each access. The reads or writes can be singular 32-bit transfers or unlimited bursts. There is no physical storage for this register.

Access: Global

Data Length in Bytes: 4

Data Format: Bit Field

Type: R/W

Default Value: 0000h

Units: N/A



10.75 DMAADDR (C7h)

Definition: Specifies the target address of a DMA read or write to system memory. This command is used for indirect access to any system memory.

Access: Global

Data Length in Bytes: 2

Data Format: Bit Field

Type: R/W

Default Value: 0000h

Units: N/A

Command							D	MAADI	DR (C7	h)						
Format								Bit F	ield							
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														0
Access	R/W	R/W													R/W	
Function		•	•	•	•	•	Se	e Follov	wing Ta	ble	•			•	•	
Default Value	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0														

Bit	Field Name	Meaning
15:13	REGION	000 - RAM
12:0	DMAADDR	The 13-bit target address

10.76 PEAK_OC_LIMIT (CDh)

Definition: Sets the peak overcurrent limit thresholds for each phase within a rail. 0.1A per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Equation: Peak Phase OC Limit = (Direct value) / 10

Units: A

Default Value: 0258h (60A)

Range: Depends on configuration

Command							PEA	<_oc_	LIMIT (CDh)						
Format								Dir	ect							
Bit Position	15	5 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Two's Complement Integer														
Default Value	0	0 0 0 0 0 0 1 0 1 0 1 1 0 0 0														



10.77 PEAK_UC_LIMIT (CEh)

Definition: Sets the peak undercurrent limit thresholds for each phase within a rail. 0.1A per LSB.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Equation: Peak Phase UC Limit = (Direct value) / 10

Units: A

Default Value: FDA8 (-60A)

Range: Depends on configuration

Command		PEAK_UC_LIMIT (CEh)														
Format								Dir	ect							
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W													R/W	
Function							Two's	Comple	ement I	nteger						
Default Value	1	1 1 1 1 1 1 0 1 1 0 1 0 1 0 0 0														

10.78 VMON_ON (D0h)

Definition: Sets the VMON pin input voltage rising threshold at which the output can be enabled. 10mV per LSB.

Access: Global

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 1C2h (4500mV)

Units: mV

Equation: VMON On = (Direct value) x 10

Range: 0mV to 32767mV

Command		VMON_ON (D0h)														
Format								Dir	ect							
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function							U	nsigne	d Intege	er						
Default Value	0	0 0 0 0 0 0 0 1 1 1 0 0 0 1 0														



10.79 VMON_OFF (D1h)

Definition: Sets the VMON pin input voltage falling threshold at which the output disables. 10mV per LSB.

Access: Global

Data Length in Bytes: 2 Data Format: Direct

Type: R/W

Default Value: 190h (4000mV)

Units: mV

Equation: VMON_OFF = (Direct value) x 10

Range: 0mV to 32767mV

Command							VI	NON_C	FF (D1	h)						
Format								Dir	ect							
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0													0	
Access	R/W	R/W												R/W		
Function							U	nsigne	d Intege	er						
Default Value	0	0 0 0 0 0 0 0 1 1 0 0 1 0 0 0														



10.80 COMPPROP (DDh)

Definition: Sets the proportional gain of the compensation loop.

Access: Paged

Data Length in Bytes: 4

Data Format: Bit Field

Type: R/W

Default Value: D90907C4h

Command							cc	MPPR	OP (DE	Dh)						
Format								Bit F	ield							
Bit Position	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table														
Default Value	1	1	0	1	1	0	0	1	0	0	0	0	1	0	0	1
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function	See Following Table															
Default Value	0	0	0	0	0	1	1	1	1	1	0	0	0	1	0	0

Bit Position	Function
31:28	Proportional gain mantissa >8 phase override, use normal P gain if value = 0 and shift = 0
27:25	Proportional gain exponent >8 phase override, use normal P gain if value = 0 and shift = 0
24:21	Proportional gain mantissa 2-phase override, use normal P gain if value = 0 and shift = 0
20	Not used
19:17	Proportional gain exponent 2-phase override, use normal P gain if value = 0 and shift = 0
16:13	Proportional gain mantissa 1-phase override, use normal P gain if value = 0 and shift = 0
12	Not used
11:9	Proportional gain exponent 1-phase override, use normal P gain if value = 0 and shift = 0
8	FIR filter length, 0 = None or 1 = ON Must be set if using D term for PID, optional if not using D term
7:4	Proportional gain mantissa is (value/8), all phase counts, if value = 0 gain is 0
3	Not used
2:0	Proportional gain exponent is 2 ⁽ shift-3), all phase counts, if value = 0 and shift = 0 gain is 0



10.81 COMPINTEG (DEh)

Definition: Sets the integral gain of the compensation loop.

Access: Paged

Data Length in Bytes: 4

Data Format: Bit Field

Type: R/W

Default Value: 00A9h

Command							cc	MPINT	EG (DI	Eh)						
Format								Bit F	ield							
Bit Position	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table														
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function	See Following Table															
Default Value	0	0	0	0	0	0	0	0	1	0	1	0	1	0	0	1

Bit Position	Function
31:16	Not used
15:12	Delay time for stepping down gain towards shift. Dcm when in DCM, in 16*clkTs per gain step
11:8	Gain when in DCM for a while
7:4	Maximum gain used when Integral movement detected Gain is 2^(-shift-1)
3:0	Gain is 2^(-shift-1)



10.82 COMPIDFF (DFh)

Definition: Sets the differential gain of the compensation loop.

Access: Paged

Data Length in Bytes: 2

Data Format: Bit Field

Type: R/W

Default Value: 0000h

Command							С	OMPDI	FF (DF	h)						
Format		Bit Field														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R	R	R/W	R/W	R	R	R/W	R/W	R	R/W						
Function							Se	e Follov	wing Ta	ble						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

Bit Number	Setting
15:13	Reserved
12	FIR filter length 0 or 1
11:8	Diff gain mantissa 1-phase override, use normal P gain if value = 0 and shift = 0
7:6	Diff gain exponent 1-phase override, use normal P gain if value = 0 and shift = 0
5:2	Differentiator gain mantissa (value/8)
1:0	Differentiator gain exponent 2 [^] (shift+1 + P-shift) range 0:3

10.83 COMPCFB (E0h)

Definition: Sets the AC current feedback gain of the compensation loop.

Access: Paged

Data Length in Bytes: 2

Data Format: Bit Field

Type: R/W

Default Value: 0560h

Command							С	OMPC	FB (E0	h)						
Format		Bit Field														
Bit Position	15	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0													0	
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		•	•	•	•	•	Se	e Follov	wing Ta	ble	•		•	•	•	•
Default Value	0	0 0 0 0 0 1 0 1 0 1 0 0 0 0 0														

Bit Number	Function
15:8	High-pass filter coefficient for current feedback
7:0	Current feedback gain, low droop cases



10.84 HS_BUS_CURRENT_SCALE (E3h)

Definition: Sets the scaling value for the high speed bus output current reporting. 16 bits with 14 fractional bits. A value of 0x4000 is a scale factor of 1.0. A value of 0x0000 is also interpreted as a scale factor of 1.0.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: 4000h (1.0)

Units: Scale Factor

Equation: HS Bus Current Scale = (Direct value) x 2⁻¹⁴

Range: 0 to 4.0

Command						HS_	BUS_0	CURRE	NT_SC	ALE (E	E3h)					
Format		Direct														
Bit Position	15	5 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function							U	nsigne	d Intege	er						
Default Value	0	0 1 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0														

10.85 PHASE_CURRENT (E4h)

Definition: Returns the individual phase current reading for the phase selected in PHASE (04h). 0.1A per LSB.

Access: Global

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: A

Equation: Phase current = (Direct value) / 10

Command							PHAS	E_CUF	RRENT	(E4h)						
Format		Direct														
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														



10.86 PHASE_TEMPERATURE (E5h)

Definition: Returns the individual phase temperature reading for the phase selected in PHASE (04h). 1°C per LSB.

Access: Global

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Units: °C

Equation: Phase Temperature = (Direct value)

Command						Р	HASE_	TEMPE	RATU	RE (E5	h)					
Format		Direct														
Bit Position	15	5 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R	R
Function		Two's Complement Integer														

10.87 PEAK_OCUC_COUNT (E9h)

Definition: Sets the number of consecutive switch cycles that can exceed the peak per-phase overcurrent limit threshold before generating a fault within a rail. A value of 0 disables the fault shutdown and produces a constant current effect.

Access: Paged

Data Length in Bytes: 2

Data Format: Bit Field

Type: R/W

Equation: Peak UC Count = (Direct value [15:8]), Peak OC Count = (Direct value [7:0])

Units: Cycles

Default Value: 0606h (6 cycles OC and 6 cycles UC)

Range: 1 cycle to 255 cycles

Command						I	PEAK_	ocuc_		T (E9h))					
Format		Bit Field														
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0														
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table														
Default Value	0	0	0	0	0	1	1	0	0	0	0	0	0	1	1	0

Bit Number	Meaning
15:8	Number of consecutive switch cycles exceeding peak UC limit before fault
7:0	Number of consecutive switch cycles exceeding peak OC limit before fault



10.88 SLOW_IOUT_OC_LIMIT (EAh)

Definition: Sets the slow sum output overcurrent fault threshold. 100mA per LSB. A value of 0 disables this function.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: C8h (20A)

Units: A

Equation: Slow I_{OUT} OC Limit = (Direct value) / 10

Range: 0A to 3276A

Command						S	LOW_I	ουτ_α	C_LIM	IT (EAI	h)					
Format		Direct														
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0										0				
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		Two's Complement Integer														
Default Value	0	0	0	0	0	0	0	0	1	1	0	0	1	0	0	0

10.89 FAST_OC_FILT_COUNT (EBh)

Definition: Sets the fast sum output overcurrent fault filter settings.

Access: Paged

Data Length in Bytes: 2

Data Format: Bit Field

Type: R/W

Default Value: 0696h (Filter = 10.6µs, Delay = 100µs)

Command						F.	AST_O	C_FILT	_cou	NT (EB	h)					
Format		Bit Field														
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0										0				
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table														
Default Value	0	0	0	0	0	1	1	0	1	0	0	1	0	1	1	0

Bit Number	Purpose	Setting
15:12	Not Used	Not used
11:8	Filter Setting	Time constant = 166.7ns * 2 ^d irect value. Range is 167ns to 5.46ms.
7:0	Delay Setting	Delay 0.667 μ s * direct value before a fault is generated. Range is 0 μ s to 170 μ s.



10.90 SLOW_OC_FILT_COUNT (ECh)

Definition: Sets the slow sum output overcurrent fault filter settings.

Access: Paged

Data Length in Bytes: 2

Data Format: Bit Field

Type: R/W

Default Value: 0606h (Filter = 10.6µs, Delay = 1024µs)

Command						SI	_ow_c	C_FIL	г_сои	NT (EC	h)					
Format		Bit Field														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table														
Default Value	0	0	0	0	0	1	1	0	0	0	0	0	0	1	1	0

Bit Number	Purpose	Setting
15:12	Not Used	Not used
11:8	Filter Setting	Time constant = 166.7ns * 2^direct value. Range is 167ns to 5.46ms.
7:0	Delay Setting	Delay 170.7 μ s * direct value before a fault is generated. Range is 0 μ s to 43.5ms.



10.91 LOOPCFG (F0h)

Definition: Configures various rail settings. To make a change, read the value, modify only the desired bits, and write the value while preserving the bit settings.

Access: Paged

Data Length in Bytes: 4

Data Format: Bit Field

Type: R/W

Default Value: 102031F6h

Command							L	OOPCI	FG (F0ł	ו)						
Format								Bit F	ield							
Bit Position	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table														
Default Value	0	0	0	1	0	0	0	0	0	0	1	0	0	0	0	0
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Function		See Following Table														
Default Value	0	0	1	1	0	0	0	1	1	1	1	1	0	1	1	0

Bit Position	Field	Function
31	Not Used	Not used
30:29	Reserved	Reserved
28	Diode Emulation Mode	1 = Enable diode emulation for power_mode 3
27:12	Reserved	Reserved
11:8	Minimum Phase Count	Minimum phase count, 0-9
7	Reserved	Reserved
6	Diode Emulation Enable	1 = Enable diode emulation
5:4	Reserved	Reserved
3:1	Reserved	Reserved
0	APD enable	1 = Enable auto phase add/drop



10.92 RESTORE_CFG (F2h)

Definition: Identifies the user configuration ID to be restored from NVM and loads the store settings into the active memory of the device. This command should only be used while all outputs are disabled. Restore takes 3ms to complete.

Access: Global

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 00h

Command				RESTORE	_CFG (F2h)									
Format		Bit Field												
Bit Position	7	7 6 5 4 3 2 1 0												
Access	R	R	R	R	R/W	R/W	R/W	R/W						
Function				See Follow	wing Table									
Default Value	0	0 0 0 0 0 0 0 0												

Bit Number	Status Bit Name	Meaning
7:4	Reserved	Reserved
3:0	CONFIG	Selected user configuration ID to restore, 0-15.



11. Adaptive Voltage Scaling (AVSBus) Functionality and Operation

The AVSBus interface provides a high speed (up to 50MHz) serial interface to the ISL68236 that allows implementation of advanced voltage scaling functions supporting increased system efficiency and performance. Devices equipped with AVSBus master capability can use the interface to enable rapid supply voltage changes to support low power consumption modes as well as high performance modes. Due to the advanced digital regulation loop employed, the ISL68236 is well equipped to support very rapid transition rates. All commands are readable at all times, but they cannot be written to unless the device is set to AVSBus control.

Function	Start Code	R/W	Command Type	Command Code	Rail Select	Command Data	CRC
Size (Bits)	2	2	1	4	4	16	3
Setting	01Ь	00b = Write data and Commit 01b = Write data, but do not commit 11b = Read Data	0b = AVSBus Data	0h = Target Rail Voltage 1h = Target Rail V _{OUT} Transition Rate 2h = Rail Current 3h = Rail Temperature 4h = Reset Rail Voltage 5h = Power Mode Eh = AVSBus Status	0h = Rail 0 1h = Rail 1 Fh = Broadcast	Read = FFh Write = See <u>AVSBus Command</u> <u>Detail</u>	
				Fh = AVSBus Version			

Table 7.	AVSBus Slave Response Subframe
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Function	Slave Ack	0b	Status Response	Command Data	Not Used	CRC
Size (Bits)	2	1	5	16	5	3
Setting	00b = Good CRC, Command acknowledged, Action Taken 01b = Good CRC, Command acknowledged, No action 10b = Bad CRC, No Action 11b = Invalid Request, No Action	0b	Bit 4 = V _{DONE} . Sets to 1 when V _{OUT} target is reached Bit 3 = Status Alert. Sets to 1 if a bit in AVSBus Status register (excluding V _{DONE}) has set Bit 2 = AVSBus Control. Sets to 1 when AVSBus control is enabled on any of the rails Bits 1:0 = Not used	Write = FFh Read = See <u>AVSBus</u> <u>Command Detail</u>	Not used 11111b	



12. AVSBus Command Detail

12.1 TARGET RAIL VOLTAGE (0h)

Definition: Sets or reads the target rail voltage set point. 1mV per LSB. The initial set point is copied from the PMBus command <u>VOUT_COMMAND (21h)</u> when AVSBus operation is selected.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: Value of PMBus VOUT COMMAND (21h)

Units: mV

Equation: TARGET RAIL VOLTAGE = (Direct value)

Range: Limited to the values of VOUT_MIN (2Bh) and VOUT_MAX (24h) PMBus commands

Command		TARGET RAIL VOLTAGE (0h)									
Format		Direct									
Bit Position	15	14	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0								
Access	R/W	R/W									
Function		Two's Complement Integer									

12.2 VOUT TRANSITION RATE (1h)

Definition: Sets or reads the rise and fall transition rates. 1mV/µs per LSB. The initial value matches PMBus transition rates until updated through AVSBus.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: R/W

Default Value: Value of PMBus <u>VOUT_TRANSITION_RATE (27h)</u> for rise and fall

Units: mV/µs

Equation: TRANSITION RATE = (Direct value)

Command		VOUT TRANSITION RATE (1h)										
Format		Direct										
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0										
Access	R/W	/ R/W R/W R/W R/W R/W R/W R/W R/W R/W R/										
Function	I	Rise Transition Rate, two's complement integer Fall Transition Rate, two's complement integer										



12.3 RAIL CURRENT (2h)

Definition: Returns the output current reading. 10mA per LSB. A filter is applied to this reading, and it is configurable in PowerNavigator.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Default Value: N/A

Units: A

Equation: RAIL CURRENT= (Direct value) / 100

Command		RAIL CURRENT (2h)								
Format		Direct								
Bit Position	15	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0								
Access	R	R R R R R R R R R R R R R R R								
Function		Two's Complement Integer								

12.4 RAIL TEMPERATURE (3h)

Definition: Returns the power stage temperature reading. 0.1°C per LSB. This value is copied from the <u>READ_TEMPERATURE_1 (8Dh)</u> PMBus command.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Read Only

Default Value: N/A

Units: °C

Equation: TEMPERATURE = (Direct value) / 10

Command		RAILTEMPERATURE (3h)									
Format		Direct									
Bit Position	15	14	14 13 12 11 10 9 8 7 6 5 4 3 2 1 0								
Access	R	R R R R R R R R R R R R R R									
Function		Two's Complement Integer									



12.5 RESET RAIL VOLTAGE (4h)

Definition: Sets TARGET RAIL VOLTAGE to match that of the <u>VOUT_COMMAND (21h)</u> PMBus command.

Access: Paged

Data Length in Bytes: 2

Data Format: Direct

Type: Write Only

Default Value: Value of PMBus VOUT_COMMAND (21h)

Units: N/A

Command		RESET RAIL VOLTAGE(4h)														
Format		Direct														
Bit Position	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Access	W	W	W	W	W	W	W	W	W	W	W	W	W	W	W	W
Function		Send all 0s														
Default Value	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0														



12.6 POWER MODE (5h)

Definition: Sets the power conversion mode. The operation is the same as the <u>POWER_MODE (34h)</u> PMBus command.

Maximum Efficiency Mode (0) defaults:

- Voltage down transitions happen immediately with decay (PWM tri-state).
- Phase dropping is enabled irrespective of the APD setting in the LOOPCFG command.
- Diode emulation can be enabled using LOOPCFG[6].

Maximum Power Mode (3) defaults:

- Voltage down transitions happen as programmed in the TOFF_DELAY and TOFF_FALL commands.
- Phase automatic add/drop is enabled using LOOPCFG[0].
- Diode emulation can be enabled using LOOPCFG[28].

MFR Defined (4) defaults:

- Voltage down transitions happen immediately with decay (PWM tri-state).
- Phase dropping is enabled irrespective of the APD setting in the LOOPCFG command.
- Diode emulation can be enabled using LOOPCFG[6] and LOOPCFG[28].

Access: Paged

Data Length in Bytes: 1

Data Format: Bit Field

Type: R/W

Default Value: 03h

Command				POWER_M	MODE (5h)								
Format		Bit Field											
Bit Position	7	7 6 5 4 3 2 1 0											
Access	R/W	R/W R/W R/W R/W R/W R/W R/W											
Function		See Following Table											
Default Value	0	0 0 0 0 0 0 1 1											

Bit Value	Setting
04h	MFR defined
03h	Maximum power
00h	Maximum efficiency



12.7 AVSBus STATUS (Eh)

Definition: Returns the device status. V_{DONE} indicates that V_{OUT} has reached the set point. OT Warn indicates that one or more of the device measured temperature exceeds the over-temperature warning threshold set by the <u>OT_WARN_LIMIT (51h)</u> PMBus command. UV Warn indicates that one or more of the device output voltages has fallen below the undervoltage warning threshold set by the <u>VIN_UV_WARN_LIMIT (58h)</u> PMBus command. The device sets the AVS_SDA line low to notify the host any time a bit in this register has been set.

Access: Paged

Data Length in Bytes: 2

Data Format: Bit Field

Type: Read Only

Default Value: N/A

Units: N/A

Command		A	VSBUS STATUS (Eh)								
Format			Bit Field								
Bit Position	15	15 14 13 12 11:0									
Access	R	R	R	R	R						
Function	VDONE	Not Used	VOUT UV Warn	OT Warn	Not Used						
Default Value	N/A	0	0	N/A	0						

12.8 AVSBus VERSION (Fh)

Definition: Returns the version of the AVSBus specification to which the device is compliant. This device complies with Version 1.3.

Access: Global

Data Length in Bytes: 2

Data Format: Bit Field

Type: Read Only

Default Value: 00h

Units: N/A



13. Revision History

Rev.	Date	Description
1.00	Oct.1.20	Initial release



For the most recent package outline drawing, see L52.6x6A.

14. Package Outline Drawing

L52.6x6A

52 Lead Quad Flat No-Lead Plastic Package Chamfered Corner Leads Rev 1, 7/14f







NOTES:

- 1. Dimensions are in millimeters. Dimensions in () for Reference Only.
- 2. Dimensioning and tolerancing conform to ASME Y14.5m-1994.
- 3. Unless otherwise specified, tolerance: Decimal ± 0.05
- **<u>A</u>** Dimension applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- 5. Tiebar shown (if present) is a non-functional feature.
- 6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.



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